

Preliminary Specifications

FEATURES:

- 8-bit 8051 Family Compatible Microcontroller (MCU) with Embedded SuperFlash Memory
- SST89E564/SST89E554 is 5V Operation
 - 0 to 40 MHz Operation at 5V
- SST89V564/SST89V554 is 3V Operation
 - 0 to 25 MHz Operation at 3V
- Fully Software and Development Toolset Compatible as well as Pin-For-Pin Package Compatible with Standard 8xC5x Microcontrollers
- 1 KByte Register/Data RAM
- Dual Block SuperFlash EEPROM
 - SST89E564/SST89V564: 64 KByte primary block + 8 KByte secondary block (128-Byte sector size)
 - SST89E554/SST89V554: 32 KByte primary block + 8 KByte secondary block (128-Byte sector size)
 - Individual Block Security Lock
 - Concurrent Operation during In-Application Programming (IAP)
 - Block Address Re-mapping
- Support External Address Range up to 64 KByte of Program and Data Memory

- Three High-Current Drive Pins (16 mA each)
- Three 16-bit Timers/Counters
- Full-Duplex Enhanced UART
 - Framing error detection
 - Automatic address recognition
- Eight Interrupt Sources at 4 Priority Levels
- Watchdog Timer (WDT)
- Four 8-bit I/O Ports (32 I/O Pins)
- · Second DPTR register
- Reduce EMI Mode (Inhibit ALE through AUXR SFR)
- SPI Serial Interface
- TTL- and CMOS-Compatible Logic Levels
- Brown-out Detection
- Extended Power-Saving Modes
 - Idle Mode
 - Power Down Mode with External Interrupt Wake-up
 - Standby (Stop Clock) Mode
- PDIP-40, PLCC-44 and TQFP-44 Packages
- Temperature Ranges:
 - Commercial (0°C to +70°C)
 - Industrial (-40°C to +85°C)

PRODUCT DESCRIPTION

SST89E564, SST89V564, SST89E554, and SST89V554 are members of the FlashFlex51 family of 8-bit microcontrollers. The FlashFlex51 is a family of microcontroller products designed and manufactured on the state-of-the-art SuperFlash CMOS semiconductor process technology. The device uses the same powerful instruction set and is pin-for-pin compatible with standard 8xC5x microcontroller devices.

The device comes with 72/40 KByte of on-chip flash EEPROM program memory using SST's patented and proprietary CMOS SuperFlash EEPROM technology with the SST's field-enhancing, tunneling injector, split-gate memory cells. The SuperFlash memory is partitioned into 2 independent program memory blocks. The primary Super-Flash Block 0 occupies 64/32 KByte of internal program memory space and the secondary SuperFlash Block 1 occupies 8 KByte of internal program memory space. The 8-KByte secondary SuperFlash block can be mapped to the lowest location of the 64/32 KByte address space; it can also be hidden from the program counter and used as an independent EEPROM-like data memory. The flash memory blocks can be programmed via a standard 87C5x OTP EPROM programmer fitted with a special adapter and firmware for SST's device. During the power-on reset, the

device can be configured as a slave to an external host for source code storage or as a master to an external host for In-Application Programming (IAP) operation. The device is designed to be programmed "In-System" and "In-Application" on the printed circuit board for maximum flexibility. The device is pre-programmed with an example of bootstrap loader in the memory, demonstrating the initial user program code loading or subsequent user code updating via the "IAP" operation. An example of bootstrap loader is for the user's reference and convenience only. SST does not guarantee the functionality or the usefulness of the sample bootstrap loader. Chip-Erase or Block-Erase operations will erase the pre-programmed sample code.

In addition to 72/40 KByte of SuperFlash EEPROM program memory on-chip, the device can address up to 64 KByte of external program memory. In addition to 1024 x 8 bits of on-chip RAM, up to 64 KByte of external RAM can be addressed.

SST's highly reliable, patented SuperFlash technology and memory cell architecture have a number of important advantages for designing and manufacturing flash EEPROMs. These advantages translate into significant cost and reliability benefits for our customers.



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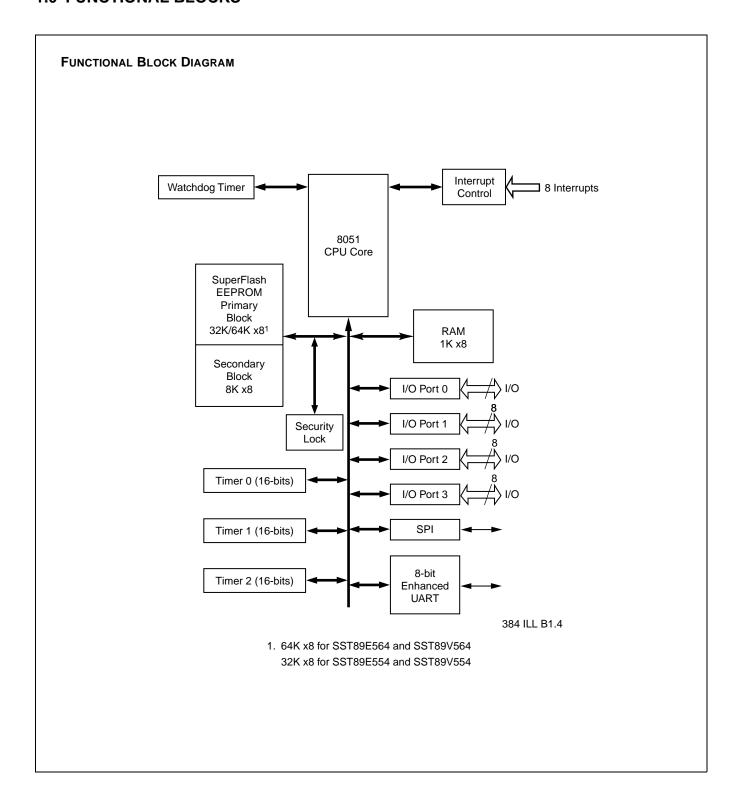
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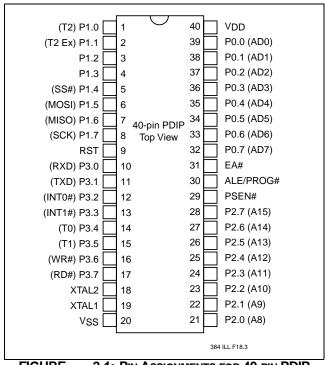
1.0 FUNCTIONAL BLOCKS





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2.0 PIN ASSIGNMENTS



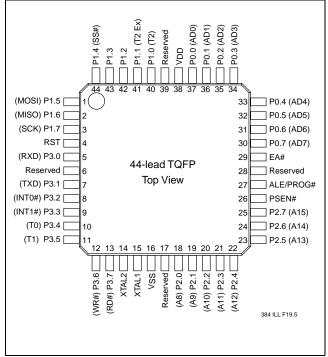


FIGURE 2-1: PIN ASSIGNMENTS FOR 40-PIN PDIP

FIGURE 2-2: PIN ASSIGNMENTS FOR 44-LEAD TQFP

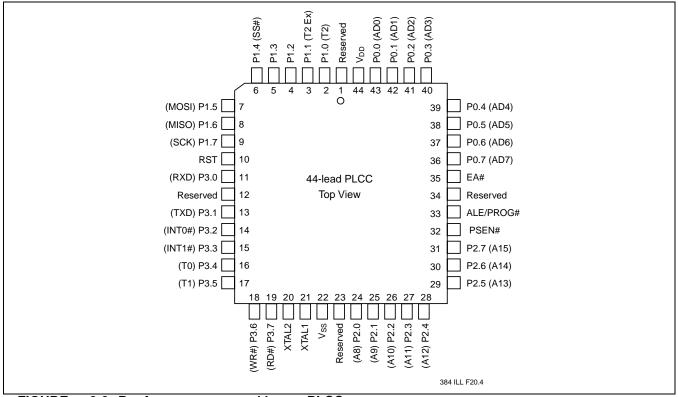


FIGURE 2-3: PIN ASSIGNMENTS FOR 44-LEAD PLCC



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2.1 Pin Descriptions

TABLE 2-1: PIN DESCRIPTIONS (1 of 2)

Symbol	Type ¹	Name and Functions
P0[7:0]	I/O	Port 0: Port 0 is an 8-bit open drain bi-directional I/O port. As an output port each pin can sink several LS TTL inputs. Port 0 pins float that have "1"s written to them, and in this state can be used as high-impedance inputs. Port 0 is also the multiplexed low-order address and data bus during accesses to external memory. In this application, it uses strong internal pullups when transitioning to V_{OH} . Port 0 also receives the code bytes during the external host mode programming, and outputs the code bytes during the external host mode verification. External pull-ups are required during program verification.
P1[7:0]	I/O with internal pull-ups	Port 1: Port 1 is an 8-bit bi-directional I/O port with internal pull-ups. The Port 1 output buffers can drive LS TTL inputs. Port 1 pins are pulled high by the internal pull-ups when "1"s are written to them and can be used as inputs in this state. As inputs, Port 1 pins that are externally pulled low will source current (I _{IL} , see Tables 10-3 and 10-4) because of the internal pull-ups. P1[5, 6, 7] have high current drive of 16 mA. Port 1 also receives the low-order address bytes during the external host mode programming and verification.
P1[0]	I/O	T2: External count input to Timer/Counter 2 or Clock-out from Timer/Counter 2
P1[1]	I	T2EX: Timer/Counter 2 capture/reload trigger and direction control
P1[4]	I/O	SS#: Master Input or Slave Output for SPI
P1[5]	I/O	MOSI: Master Output line, Slave Input line for SPI
P1[6]	I/O	MISO: Master Input line, Slave Output line for SPI
P1[7]	I/O	SCK: Master clock output, slave clock input line for SPI
P2[7:0]	I/O with internal pull-ups	Port 2: Port 2 is an 8-bit bi-directional I/O port with internal pull-ups. Port 2 pins are pulled high by the internal pull-ups when "1"s are written to them and can be used as inputs in this state. As inputs, Port 2 pins that are externally pulled low will source current (I _{IL} , see Tables 10-3 and 10-4) because of the internal pull-ups. Port 2 sends the high-order address byte during fetches from external Program memory and during accesses to external Data Memory that use 16-bit address (MOVX@DPTR). In this application, it uses strong internal pull-ups when transitioning to V _{OH} . Port 2 also receives some control signals and a partial of high-order address bits during the external host mode programming and verification.
P3[7:0]	I/O with internal pull-ups	Port 3: Port 3 is an 8-bit bidirectional I/O port with internal pull-ups. The Port 3 output buffers can drive LS TTL inputs. Port 3 pins are pulled high by the internal pull-ups when "1"s are written to them and can be used as inputs in this state. As inputs, Port 3 pins that are externally pulled low will source current (I _{IL} , see Tables 10-3 and 10-4) because of the internal pull-ups. Port 3 also receives some control signals and a partial of high-order address bits during the external host mode programming and verification.
P3[0]	I	RXD: Serial input line
P3[1]	0	TXD: Serial output line
P3[2]	I	INT0#: External Interrupt 0 Input
P3[3]	I	INT1#: External Interrupt 1 Input
P3[4]	I	T0: External count input to Timer/Counter 0
P3[5]	I	T1: External count input to Timer/Counter 1
P3[6]	0	WR#: External Data Memory Write strobe
P3[7]	0	RD#: External Data Memory Read strobe
PSEN#	I/O	Program Store Enable: PSEN# is the Read strobe to External Program Store. When the device is executing from Internal Program Memory, PSEN# is inactive (V _{OH}). When the device is executing code from External Program Memory, PSEN# is activated twice each machine cycle, except when access to External Data Memory while one PSEN# activation is skipped in each machine cycle. A forced high-to-low input transition on the PSEN# pin while the RST input is continually held high for more than ten machine cycles will cause the device to enter External Host mode for programming.



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TABLE 2-1: PIN DESCRIPTIONS (CONTINUED) (2 OF 2)

Symbol	Type ¹	Name and Functions
RST	I	Reset: While the oscillator is running, a high logic state on this pin for two machine cycles will reset the device. After a reset, if the PSEN# pin is driven by a high-to-low input transition while the RST input pin is held high, the device will enter the External Host mode, otherwise the device will enter the Normal operation mode.
EA#	I	External Access Enable: EA# must be driven to V_{IL} in order to enable the device to fetch code from the External Program Memory. EA# must be driven to V_{IH} for internal program execution. However, Security lock level 4 will disable EA#, and program execution is only possible from internal program memory. The EA# pin can tolerate a high voltage ² of 12V (see "Absolute Maximum Stress Ratings" on page 47).
ALE/PROG#	I/O	Address Latch Enable: ALE is the output signal for latching the low byte of the address during accesses to external memory. This pin is also the programming pulse input (PROG#) for the external host mode. ALE is activated twice each machine cycle, except when access to External Data Memory, one ALE activation is skipped in the second machine cycle. However, if AO is set to 1, ALE is disabled. (see "Auxiliary Register (AUXR)" on page 20)
XTAL1 XTAL2	I 0	Oscillator: Input and output to the inverting oscillator amplifier. XTAL1 is input to internal clock generation circuits from an external clock source.
V_{DD}	l	Power Supply: Supply voltage during normal, Idle, Power Down, and Standby Mode operations.
Vss	1	Ground: Circuit ground. (0V reference)

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^{1.} I = Input; O = Output

^{2.} It is not necessary to receive a 12V programming supply voltage during flash programming.



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3.0 MEMORY ORGANIZATION

The device has separate address spaces for program and data memory.

3.1 Program Memory

There are two internal flash memory blocks in the device. The primary flash memory block (Block 0) has 64/32 KByte. The secondary flash memory block (Block 1) has 8 KByte. Since the total program address space is limited to 64/32 KByte, the SFCF[1:0] bit are used to control Program

Bank Selection. Please refer to Figure 3-1 and Figure 3-2 for the program memory configurations. Program Bank Select is described in the next section.

The 64K/32K x8 primary SuperFlash block is organized as 512/256 sectors, each sector consists of 128 Bytes.

The 8K x8 secondary SuperFlash block is organized as 64 sectors, each sector consists also of 128 Bytes.

For both blocks, the 7 least significant program address bits select the byte within the sector. The remainder of the program address bits select the sector within the block.

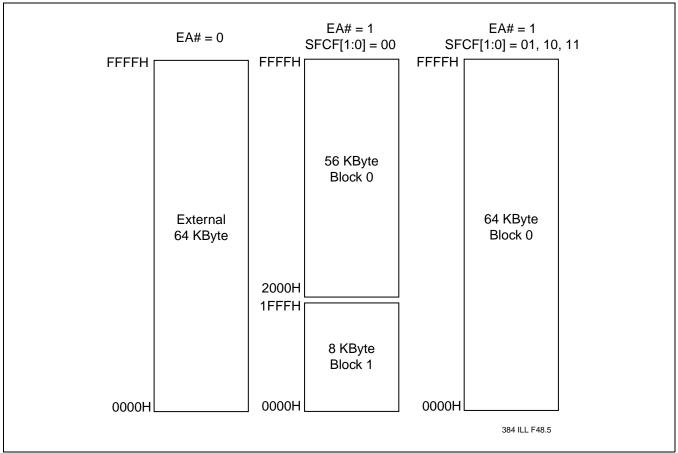


FIGURE 3-1: PROGRAM MEMORY ORGANIZATION FOR SST89E564 AND SST89V564



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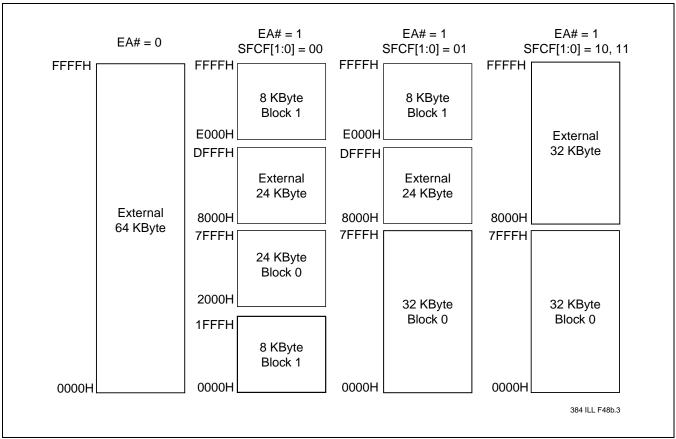


FIGURE 3-2: PROGRAM MEMORY ORGANIZATION FOR SST89E554 AND SST89V554

3.2 Program Memory Block Switching

The program memory block switching feature of the device allows either Block 1 or the lowest 8 KByte of Block 0 to be used for the lowest 8 KByte of the program address space. SFCF[1:0] controls program memory block switching.

TABLE 3-1: SFCF Values for Program Memory Block Switching for SST89E564/SST89V564

SFCF[1:0]	Program Memory Block Switching
01, 10, 11	Block 1 is not visible to the PC; Block 1 is reachable only via In-Application Programming from 000H - 1FFFH.
00	Block 1 is overlaid onto the low 8K of the program address space; occupying address locations 0000H - 1FFFH. When the PC falls within 0000H - 1FFFH, the instruction will be fetched from Block 1 instead of Block 0. Outside of 0000H - 1FFFH, Block 0 is used. Locations 0000H - 1FFFH of Block 0 are reachable through In-Application Programming.

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TABLE 3-2: SFCF Values for Program Memory Block Switching for SST89E554/SST89V554

SFCF[1:0]	Program Memory Block Switching
10, 11	Block 1 is not visible to the PC; Block 1 is reachable only via In-Application Programming from E000H - FFFFH.
01	Both Block 0 and Block 1 are visible to the PC. Block 0 is occupied from 0000H - 7FFFH. Block 1 is occupied from E000H - FFFFH.
00	Block 1 is overlaid onto the low 8K of the program address space; occupying address locations 0000H - 1FFFH. When the PC falls within 0000H - 1FFFH, the instruction will be fetched from Block 1 instead of Block 0. Outside of 0000H - 1FFFH, Block 0 is used. Locations 0000H - 1FFFH of Block 0 are reachable through In-Application Programming.

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3.2.1 Reset Configuration of Program Memory Block Switching

Program memory block switching is initialized after reset according to the state of the Start-up Configuration bit SC0. The SC0 bit is programmed via an External Host Mode command or an IAP Mode command. See Table 4-2 and Table 4-6.

Once out of reset, the SFCF[0] bit can be changed dynamically by the program for desired effects. Changing SFCF[0] will not change the SC0 bit.

Caution must be taken when dynamically changing the SFCF[0] bit. Since this will cause different physical memory to be mapped to the logical program address space. The user must avoid executing block switching instructions within the address range 0000H to 1FFFH.

TABLE 3-3: SFCF Values Under Different Reset Conditions

		State of SFCF[1:0] after:									
SC1 ¹	SC0	Power-on or External Reset	WDT Reset or Brown-out Reset	Software Reset							
1	1	00 (default)	х0	10							
1	0	01	x1	11							
0	1	10	10	10							
0	0	11	11	11							

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1. SC1 only applies to SST89E554 and SST89V554.

3.3 Data Memory

The device has 1024 x 8 bits of on-chip RAM and can address up to 64 KByte of external data memory.

The device has four sections of internal data memory:

- 1. The lower 128 Bytes of RAM (00H to 7FH) are directly and indirectly addressable.
- 2. The higher 128 Bytes of RAM (80H to FFH) are indirectly addressable.
- 3. The Special Function Registers (SFRs, 80H to FFH) are directly addressable only.
- 4. The expanded RAM of 768 Bytes (00H to 2FFH) is indirectly addressable by the move external instruction (MOVX) and clearing the EXTRAM bit. (See "Auxiliary Register (AUXR)" on page 20)

3.4 Dual Data Pointers

The device has two 16-bit data pointers. The DPTR Select (DPS) bit in AUXR1 determines which of the two data pointers is accessed. When DPS=0, DPTR0 is selected; when DPS=1, DPTR1 is selected. Quickly switching between the two data pointers can be accomplished by a single INC instruction on AUXR1.

3.5 Special Function Registers (SFR)

Most of the unique features of the FlashFlex51 microcontroller family are controlled by bits in special function registers (SFRs) located in the SFR Memory Map shown in Table 3-4. Individual descriptions of each SFR are provided and Reset values indicated in Tables 3-5 to 3-9.



FFH F7H EFH E7H DFH C7H C7H BFH AFH A7H 9FH 97H 8FH

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TABLE 3-4: FLASHFLEX51 SFR MEMORY MAP

				8 BY	TES			
F8H	IPA ¹							
F0H	B ¹							IPAH
E8H	IEA ¹							
E0H	ACC ¹							
D8H								
D0H	PSW ¹					SPCR		
C8H	T2CON1	T2MOD	RCAP2L	RCAP2H	TL2	TH2		
C0H	WDTC ¹							
B8H	IP ¹	SADEN						
B0H	P3 ¹	SFCF	SFCM	SFAL	SFAH	SFDT	SFST	IPH
A8H	IE ¹	SADDR	SPSR					
A0H	P2 ¹		AUXR1					
98H	SCON ¹	SBUF						
90H	P1 ¹							
88H	TCON1	TMOD	TL0	TL1	TH0	TH1	AUXR	
80H	P0 ¹	SP	DPL	DPH		WDTD	SPDR	PCON

1. SFRs are bit addressable.

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TABLE 3-5: CPU RELATED SFRS

		Direct	Bit Address, Symbol, or Alternative Port Function							RESET	
Symbol	Description	Address	MSB							LSB	Value
ACC ¹	Accumulator	E0H				ACC	[7:0]				00H
B ¹	B Register	F0H				B[7	' :0]				00H
PSW ¹	Program Status Word	D0H	CY	Y AC F0 RS1 RS0 OV F1 P						00H	
SP	Stack Pointer	81H		•		SP[7:0]		•	•	07H
DPL	Data Pointer Low	82H		DPL[7:0]							00H
DPH	Data Pointer High	83H		DPH[7:0]							00H
IE ¹	Interrupt Enable	A8H	EA	-	ET2	ES0	ET1	EX1	ET0	EX0	40H
IEA ¹	Interrupt Enable A	E8H	-	-	-	-	EBO	-	-	-	xxxx0xxxb
IP ¹	Interrupt Priority Reg	B8H	-	-	PT2	PS	PT1	PX1	PT0	PX0	xx000000b
IPH	Interrupt Priority Reg High	В7Н	-	-	PT2H	PSH	PT1H	PX1H	PT0H	PX0H	xx000000b
IPA ¹	Interrupt Priority Reg A	F8H	-	-	-	-	РВО	-	-	-	xxxx0xxxb
IPAH	Interrupt Priority Reg A High	F7H	-	-	-	-	PBO H	-	-	-	xxxx0xxxb
PCON	Power Control	87H	SMOD1	SMOD0	BOF	POF	GF1	GF0	PD	IDL	00010000b
AUXR	Auxiliary Reg	8EH	-	-	-	-	-	-	EXTRAM	AO	xxxxxxx00b
AUXR1	Auxiliary Reg 1	A2H	-	-	-	-	GF2	0	-	DPS	xxxx00x0b

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1. Bit Addressable SFRs

TABLE 3-6: FLASH MEMORY PROGRAMMING SFRS

		Direct		Bit Addr	Bit Address, Symbol, or Alternative Port Function						
Symbol	Description	Address	MSB		LSB						Value
SFST	SuperFlash Status	В6Н	SECD1	SECD2	SECD3	-	-	FLASH_BUSY	-	-	xxxxx0xxb
SFCF	SuperFlash Configuration	B1H	-	IAPEN	-	-	-	-	SWR	BSEL	x0xxxxxxb
SFCM	SuperFlash Command	B2H	FIE		FCM						00H
SFDT	SuperFlash Data	B5H		SuperFlash Data Register						00H	
SFAL	SuperFlash Address Low	ВЗН	Sup	SuperFlash Low Order Byte Address Register - A ₇ toA ₀ (SFAL)						00H	
SFAH	SuperFlash Address High	B4H	Supe	erFlash Hi	gh Order E	yte A	ddres	s Register - A ₁₅ to	A ₈ (SFA	AH)	00H

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TABLE 3-7: WATCHDOG TIMER SFRS

		Direct		Bit Address, Symbol, or Alternative Port Function							
Symbol	Description	Address	MSB	ISB LSB							
WDTC ¹	Watchdog Timer Control	C0H	-	WDOUT WDRE WDTS WDT SWDT							
WDTD	Watchdog Timer Data/Reload	85H	Watchdog Timer Data/Reload							00H	

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TABLE 3-8: TIMER/COUNTERS SFRs

		Direct	ı	Bit Address, Symbol, or Alternative Port Function								
Symbol	Description	Address	MSB							LSB	Value	
TMOD	Timer/Counter	89H		Tim	er 1			Tii	mer 0		00H	
	Mode Control		GATE	C/T#	M1	M0	GATE	C/T#	M1	M0		
TCON ¹	Timer/Counter Control	88H	TF1 TR1 TF0 TR0 IE		IE1	IT1	IE0	IT0	00H			
TH0	Timer 0 MSB	8CH		TH0[7:0]							00H	
TL0	Timer 0 LSB	8AH		TL0[7:0]								
TH1	Timer 1 MSB	8DH		TH1[7:0]								
TL1	Timer 1 LSB	8BH				T	L1[7:0]				00H	
T2CON ¹	Timer / Counter 2 Control	C8H	TF2	EXF2	RCLK	TCLK	EXEN2	TR2	C/T2#	CP/RL2#	00H	
T2MOD#	Timer2 Mode Control	С9Н	-	-	-	-	-	-	T2OE	DCEN	xxxxxx00b	
TH2	Timer 2 MSB	CDH		TH2[7:0]							00H	
TL2	Timer 2 LSB	CCH	TL2[7:0]							00H		
RCAP2H	Timer 2 Capture MSB	СВН		RCAP2H[7:0]							00H	
RCAP2L	Timer 2 Capture LSB	CAH				RCA	AP2L[7:0]			· · · · · · · · · · · · · · · · · · ·	00H	

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1. Bit Addressable SFRs

^{1.} Bit Addressable SFRs



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TABLE 3-9: INTERFACE SFRs

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		Direct	Bi	t Addres	s, Symb	ol, or Al	ternativ	e Port F	unction	l	RESET	
Symbol	Description	Address	MSB							LSB	Value	
SBUF	Serial Data Buffer	99H		SBUF[7:0]								
SCON1	Serial Port Control	98H	SM0/FE	SM1	SM2	REN	TB8	RB8	TI	RI	00H	
SADDR	Slave Address	А9Н				SADDR#	# [7:0]				00H	
SADEN	Slave Address Mask	В9Н		SADEN#[7:0]								
SPCR	SPI Control Register	D5H	SPIE	SPE	DORD	MSTR	CPOL	СРНА	SPR1	SPR0	04H	
SPSR	SPI Status Register	AAH	SPIF	WCOL							00H	
SPDR	SPI Data Register	86H	SPD7	SPD6	SPD5	SPD4	SPD3	SPD2	SPD1	SPD0	00H	
P0 ¹	Port 0	80H		P0[7:0]								
P1 ¹	Port 1	90H	-	-	-	-	-	-	T2EX	T2	FFH	
P2 ¹	Port 2	A0H		P2[7:0]								
P3 ¹	Port 3	вон	RD#	WR#	T1	T0	INT1#	INT0#	TXD	RXD	FFH	

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1. Bit Addressable SFRs



Preliminary Specifications

SuperFlash Status Register (SFST) (Read Only Register)

Locatior	١
0B6H	

7	6	5	4	3	2	1	0
SECD1	SECD2	SECD3	-	-	FLASH_BUSY	-	-

Reset Value xxxxx0xxb

SymbolFunctionSECD1Security bit 1.SECD2Security bit 2.SECD3Security bit 3.

Please refer to Table 4-6 for security lock options.

FLASH_BUSYFlash operation completion polling bit.

1: Device is busy with flash operation.

0: Device has fully completed the last command.

SuperFlash Configuration Register (SFCF)

Loca	ation
0B	1H

7	6	5	4	3	2	1	0
-	IAPEN		1	-	-	SWR	BSEL

Reset Value x0xxxxxxxb

Symbol Function

IAPEN Enable IAP operation

0: IAP commands are disabled1: IAP commands are enabled

SWR Software Reset

See "9.2 Software Reset" on page 43

BSEL Program memory block switching bit

See Figures 3-1 and 3-2.

SuperFlash Command Register (SFCM)

Location	
0B2H	

7	6	5	4	3	2	1	0
FIE	FCM6	FCM5	FCM4	FCM3	FCM2	FCM1	FCM0

Reset Value

Symbol Function

FIE Flash Interrupt Enable.

0: INT1# is not reassigned.

1: INT1# is re-assigned to signal IAP operation completion.

External INT1# interrupts are ignored.

FCM[6:0] Flash operation command

000 1011b Sector-Erase 000_1101b Block-Erase 000 1100b Byte-Verify¹ 000_1110b Byte-Program 000_1111b Prog-SB1 000 0011b Prog-SB2 000 0101b Prog-SB3 Prog-SC0 000_1001b

All other combinations are not implemented, and reserved for future use.

1. Byte-Verify has a single machine cycle latency and will not generate any INT1# interrupt regardless of FIE.



Preliminary Specifications

SuperFlash Data Register (SFDT)

Location	7	6	5	4	3	2	1	0	Reset Value
0B5H			,	SuperFlash [Data Registe	r			00000000b

Symbol Function

SFDT Mailbox register for interfacing with flash memory block. (Data register).

SuperFlash Address Registers (SFAL)

Location	7	6	5	4	3	2	1	0	Reset Value
0B3H			SuperFlas	h Low Order	Byte Addres	ss Register			0000000b

Symbol Function

SFAL Mailbox register for interfacing with flash memory block. (Low order address register).

SuperFlash Address Registers (SFAH)

Location	7	6	5	4	3	2	1	0	Reset Value
0B4H			SuperFlash	n High Order	Byte Addres	ss Register			0000000b

Symbol Function

SFAH Mailbox register for interfacing with flash memory block. (High order address register).

Interrupt Enable (IE)

Location	7	6	5	4	3	2	1	0	Reset Value
A8H	EA	-	ET2	ES	ET1	EX1	ET0	EX0	00H

Symbol **Function** EΑ Global Interrupt Enable. 0 = Disable1 = Enable ET2 Timer 2 Interrupt Enable. ES Serial Interrupt Enable. ET1 Timer 1 Interrupt Enable. EX1 External 1 Interrupt Enable. ET0 Timer 0 Interrupt Enable. EX0 External 0 Interrupt Enable.

Interrupt Enable A (IEA)

Location	7	6	5	4	3	2	1	0	Reset Value
E8H	-	-	-	-	EBO	-	-	-	xxxx0xxxb

Symbol Function

EBO Brown-out Interrupt Enable.

1 = Enable the interrupt0 = Disable the interrupt



Preliminary Specifications

Interrupt Priority (IP)

Location
B8H

7	6	5	4	3	2	1	0
-	-	PT2	PS	PT1	PX1	PT0	PX0

Reset Value xx000000b

Symbol	Function
PT2	Timer 2 interrupt priority bit.
PS	Serial Port interrupt priority bit.
PT1	Timer 1 interrupt priority bit.
PX1	External interrupt 1 priority bit.
PT0	Timer 0 interrupt priority bit.
PX0	External interrupt 0 priority bit.

Interrupt Priority High (IPH)

Locatio	r
B7H	

7	6	5	4	3	2	1	0
-	-	PT2H	PSH	PT1H	PX1H	PT0H	PX0H

Reset Value xx000000b

Symbol	Function
PT2H	Timer 2 interrupt priority bit high.
PSH	Serial Port interrupt priority bit high.
PT1H	Timer 1 interrupt priority bit high.
PX1H	External interrupt 1 priority bit high.
PT0H	Timer 0 interrupt priority bit high.
PX0H	External interrupt 0 priority bit high.

Interrupt Priority A (IPA)

Location
F8H

7	6	5	4	3	2	1	0
-	-	-	-	PBO	-	-	-

Reset Value xxxx0xxxb

ction

PBO Brown-out interrupt priority bit.

Interrupt Priority A High (IPAH)

Locatio	r
F7H	

7	6	5	4	3	2	1	0
-	-	-	-	PBOH	-	-	-

Reset Value xxxx0xxxb

Symbol Function

PBOH Brown-out Interrupt priority bit high.



Preliminary Specifications

Auxiliary Register (AUXR)

Location	
8EH	

7	6	5	4	3	2	1	0
-	-	-	-	-	-	EXTRAM	AO

Symbol Function

EXTRAM 0: Internal Expanded RAM access. For details, refer to "Data Memory" on page 12.

1: External data memory access.

AO 0: Normal ALE

1: ALE is normally off. ALE is active only during a MOVX or MOVC instruction. This will reduce

EMI.

Auxiliary Register 1 (AUXR1)

Location
A2H

7	6	5	4	3	2	1	0
	-	-	-	GF2	0	-	DPS

Reset Value xxxx00x0b

Reset Value

Symbol Function

GF2 General purpose user-defined flag.

DPS DPTR registers select bit.

0: DPTR0 is selected.1: DPTR1 is selected.

Watchdog Timer Control Register (WDTC)

Location 0C0H

7	6	5	4	3	2	1	0
-	-	-	WDOUT	WDRE	WDTS	WDT	SWDT

Reset Value

Symbol Function

WDOUT Watchdog output enable.

0: Watchdog reset will not be exported on Reset pin.

1: Watchdog reset if enabled by WDRE, will assert Reset pin for 32 clocks.

WDRE Watchdog timer reset enable.

0: Disable watchdog timer reset.

1: Enable watchdog timer reset.

WDTS Watchdog timer reset flag.

0: External hardware reset clears the flag.

Flag can also be cleared by writing a 1.

Flag survives if chip reset happened because of watchdog timer overflow.

1: Hardware sets the flag on watchdog overflow.

WDT Watchdog timer refresh.

0: Hardware resets the bit when refresh is done.

1: Software sets the bit to force a watchdog timer refresh.

SWDT Start watchdog timer.

0: Stop WDT. 1: Start WDT.



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Watchdog Timer Data/Reload Register (WDTD)

Location	7	6	5	4	3	2	1	0	Reset Value
085H			Wat	tchdog Time	er Data/Rel	oad			00000000b

Symbol Function

WDTD Initial/Reload value in Watchdog Timer. New value won't be effective until WDT is set.

SPI Control Register (SPCR)

Location	7	6	5	4	3	2	1	0	Reset Value
D5H	SPIE	SPE	DORD	MSTR	CPOL	CPHA	SPR1	SPR0	00000100b

Symbol Function

SPIE If both SPIE and ES are set to one, SPI interrupts are enabled.

SPE SPI enable bit.

0: Disables SPI.

1: Enables SPI and connects SS#, MOSI, MISO, and SCK to pins P1[4], P1[5], P1[6], P1[7].

DORD Data Transmission Order.

0: MSB first in data transmission.1: LSB first in data transmission.

MSTR Master/Slave select.

0: Selects Slave mode.1: Selects Master mode.

CPOL Clock Polarity

0: SCK is low when idle (Active High).

1: SCK is high when idle (Active Low).

CPHA Clock Phase control bit.

0: Shift triggered on the leading edge of the clock.

1: Shift triggered on the trailing edge of the clock.

SPR1, SPR0 SPI Clock Rate Select bits. These two bits control the SCK rate of the device configured as master. SPR1 and SPR0 have no effect on the slave. The relationship between SCK and the oscillator frequency, f_{OSC}, is as follows:

SPR1	SPR0	SCK = f _{OSC} divided by
0	0	4
0	1	16
1	0	64
1	1	128



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SPI Status Register (SPSR)

Location
AAH

7	6	5	4	3	2	1	0	Reset Value
SPIF	WCOL	-	-	-	-	-	-	00xxxxxxb

Symbol Function

SPIF Upon completion of data transfer, this bit is set to 1. If SPIE =1 and ES =1, an interrupt is

then generated. To clear, read SPSR and then access SPDR.

WCOL Set if the SPI data register is written to during data transfer. To clear, read SPSR and

then access SPDR.

SPI Data Register (SPDR)

Location	
86H	

7	6	5	4	3	2	1	0
SPD7	SPD6	SPD5	SPD4	SPD3	SPD2	SPD1	SPD0

Reset Value 00H

Power Control Register (PCON)

Location	
87H	

7	6	5	4	3	2	1	0
SMOD1	SMOD0	BOF	POF	GF1	GF0	PD	IDL

Reset Value

Symbol Function

SMOD1 Double Baud rate bit. If SMOD1 = 1, Timer 1 is used to generate the baud rate.

SMOD0 FE/SM0 Selection bit.

0: SCON[7] = SM0 1: SCON[7] = FE,

BOF Brown-out detection status bit, this bit will not be affected by any other reset. BOF should

be cleared by software. Power-on reset will also clear the BOF bit.

0: No Brown-out.

1: Brown-out occurred

POF Power-on reset status bit, this bit will not be affected by any other reset. POF should be

cleared by software.

0: No Power-on reset.

1: Power-on reset occurred

GF1 General-purpose flag bit.

GF0 General-purpose flag bit.

PD Power-down bit.

0: Power-down mode is not activated.

1: Activates Power-down mode.

IDL Idle mode bit.

0: Idle mode is not activated.

1: Activates Idle mode.



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Serial Port Control Register (SCON)

Location
98H

7	6	5	4	3	2	1	0	Reset Value
SM0/FE	SM1	SM2	REN	TB8	RB8	TI	RI	0000000b

Symbol Function

FE Set SMOD0 = 1 to access FE bit.

0: No framing error

1: Framing Error. Set by receiver when an invalid stop bit is detected. This bit needs to

be cleared by software.

SMOD0 = 0 to access SM0 bit.

Serial Port Mode Bit 0

SM1 Serial Port Mode Bit 1

SM0	SM1	Mode	Description	Baud Rate ¹
0	0	0	Shift Register	f _{OSC} /6 (6 clock mode) or f _{OSC} / 12 (12 clock mode)
0	1	1	8-bit UART	Variable
1	0	2	9-bit UART	f _{OSC} /32 or f _{OSC} /16 (6 clock mode) or f _{OSC} /64 or f _{OSC} /32 (12 clock mode)
1	1	3	9-bit UART	Variable

^{1.} f_{OSC} = oscillator frequency

SM2

Enables the Automatic Address Recognition feature in Modes 2 or 3. If SM2 = 1 then RI will not be set unless the received 9th data bit (RB8) is 1, indicating an address, and the received byte is a Given or broadcast Address. In Mode 1, if SM2 = 1 then RI will not be activated unless a valid stop bit was received, and the received byte is a Given or Broadcast Address. In Mode 0, SM2 should be 0.

REN

Enables serial reception.

0: to disable reception.

1: to enable reception.

TB8

The 9th data bit that will be transmitted in Modes 2 and 3. Set or clear by software as

desired.

RB8

In Modes 2 and 3, the 9th data bit that was received. In Mode 1, if SM2 - 0, RB8 is the

stop bit that was received. In Mode 0, RB8 is not used.

ΤI

Transmit interrupt flag. Set by hardware at the end of the 8th bit time in Mode 0, or at the beginning of the stop bit in the other modes, in any serial transmission, Must be cleared

by software.

RI

Receive interrupt flag. Set by hardware at the end of the8th bit time in Mode 0, or halfway through the stop bit time in the other modes, in any serial reception (except see SM2).

Must be cleared by software.



Preliminary Specifications

4.0 FLASH MEMORY PROGRAMMING

The device internal flash memory can be programmed or erased using the following two methods:

- External Host Mode
- In-Application Programming (IAP) Mode

4.1 External Host Programming Mode

External Host Programming Mode allows the user to program the flash memory directly without using the CPU. External Host Mode is entered by forcing PSEN# from a

logic high to a logic low while RST input is being held continuously high. The device will stay in External Host Mode as long as RST = 1 and PSEN# = 0.

A Read-ID operation is necessary to "arm" the device in External Host Mode, and no other External Host Mode commands can be enabled until a Read-ID is performed. In External Host Mode, the internal flash memory blocks are accessed through the re-assigned I/O port pins (see Figure 4-1 for details) by an external host, such as a MCU programmer, a PCB tester or a PC-controlled development board.

TABLE 4-1: EXTERNAL HOST MODE COMMANDS FOR SST89E564/SST89V564

			PROG#/							P3[5:4]	
Operation	RST	PSEN#	ALE	EA#	P3[7]	P3[6]	P2[7]	P2[6]	P0[7:0]	P2[5:0]	P1[7:0]
Read-ID	V _{IH1}	V_{IL}	V_{IH}	V_{IH}	V_{IL}	V _{IL}	V_{IL}	V_{IL}	DO	AH	AL
Chip-Erase	V _{IH1}	V_{IL}	\downarrow	V_{IH}	V_{IH}	V_{IL}	V_{IL}	V_{IL}	Х	Х	Х
Block-Erase	V_{IH1}	V_{IL}	\downarrow	V_{IH}	V_{IH}	V_{IH}	V_{IL}	V_{IH}	Х	Х	Х
Sector-Erase	V _{IH1}	V_{IL}	\downarrow	V_{IH}	V_{IH}	V_{IL}	V_{IH}	V_{IH}	X	AH	AL
Byte-Program	V _{IH1}	V_{IL}	\downarrow	V_{IH}	V_{IH}	V _{IH}	V_{IH}	V_{IL}	DI	AH	AL
Byte-Verify (Read)	V _{IH1}	V_{IL}	V_{IH}	V_{IH}	V_{IH}	V_{IH}	V_{IL}	V_{IL}	DO	AH	AL
Select-Block0	V _{IH1}	V_{IL}	\downarrow	V_{IH}	V_{IH}	VII	VII	V_{IH}	X	55H	Х
Select-Block1	V _{IH1}	V_{IL}	\downarrow	V_{IH}	V_{IH}	VII	VII	V_{IH}	Х	A5H	Х
Prog-SC0	V _{IH1}	V_{IL}	\downarrow	V_{IH}	V_{IH}	V_{IL}	V_{IL}	V_{IH}	X	5AH	Х
Prog-SB1	V _{IH1}	V_{IL}	\downarrow	V_{IH}	V_{IH}	V _{IH}	V_{IH}	V_{IH}	Х	Х	Х
Prog-SB2	V _{IH1}	V_{IL}	\downarrow	V_{IH}	V_{IL}	V _{IL}	V_{IH}	V_{IH}	X	Х	Х
Prog-SB3	V _{IH1}	V_{IL}	\downarrow	V_{IH}	V_{IL}	V_{IH}	V_{IL}	V_{IH}	X	X	Χ

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Note: V_{IL} = Input Low Voltage; V_{IH} = Input High Voltage; V_{IH1} = Input High Voltage (XTAL, RST); X = Don't care; AL = Address low order byte; AH = Address high order byte; DI = Data Input; DO = Data Output



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TABLE 4-2: EXTERNAL HOST MODE COMMANDS FOR SST89E554/SST89V554

Omeration	ВСТ	PSEN#	PROG#/	-A#	D2[7]	Datei	DOUZI	Datel	D0[7.0]	P3[5:4]	D4[7.0]
Operation	RST	PSEN#	ALE	EA#	P3[7]	P3[6]	P2[7]	P2[6]	P0[7:0]	P2[5:0]	P1[7:0]
Read-ID	V_{IH1}	V_{IL}	V_{IH}	V_{IH}	V_{IL}	V_{IL}	V_{IL}	V_{IL}	DO	AH	AL
Chip-Erase	V_{IH1}	V_{IL}	\downarrow	V_{IH}	V_{IH}	V_{IL}	V_{IL}	V_{IL}	Х	Х	Χ
Block-Erase	V_{IH1}	V_{IL}	\downarrow	V_{IH}	V_{IH}	V_{IH}	V_{IL}	V_{IH}	Х	A[15:13]	Χ
Sector-Erase	V_{IH1}	V_{IL}	\downarrow	V_{IH}	V_{IH}	V_{IL}	V_{IH}	V_{IH}	Х	AH	AL
Byte-Program	V_{IH1}	V_{IL}	\downarrow	V_{IH}	V_{IH}	V _{IH}	V_{IH}	V_{IL}	DI	AH	AL
Byte-Verify (Read)	V_{IH1}	V_{IL}	V_{IH}	V_{IH}	V_{IH}	V_{IH}	V_{IL}	V_{IL}	DO	AH	AL
Prog-SC0	V_{IH1}	V_{IL}	\downarrow	V_{IH}	V_{IH}	V_{IL}	V_{IL}	V_{IH}	Х	5AH	Х
Prog-SC1	V_{IH1}	V_{IL}	\downarrow	V_{IH}	V_{IH}	V_{IL}	V_{IL}	V_{IH}	Χ	AAH	Χ
Prog-SB1	V_{IH1}	V_{IL}	\downarrow	V_{IH}	V_{IH}	V_{IH}	V_{IH}	V_{IH}	Х	Х	Х
Prog-SB2	V_{IH1}	V_{IL}	\downarrow	V_{IH}	V_{IL}	V_{IL}	V_{IH}	V_{IH}	Х	Х	Χ
Prog-SB3	V _{IH1}	V_{IL}	\downarrow	V _{IH}	V_{IL}	V _{IH}	V _{IL}	V _{IH}	Х	Х	Χ

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Note: Symbol ↓ signifies a negative pulse and the command is asserted during the low state of PROG#/ALE input. All other combinations of the above input pins are invalid and may result in unexpected behaviors.

Note: V_{IL} = Input Low Voltage; V_{IH} = Input High Voltage; V_{IH1} = Input High Voltage (XTAL, RST); X = Don't care; AL = Address low order byte; AH = Address high order byte; DI = Data Input; DO = Data Output; A[15:13] = 0xxb for Block 0 and A[15:13] = 111b for Block 1

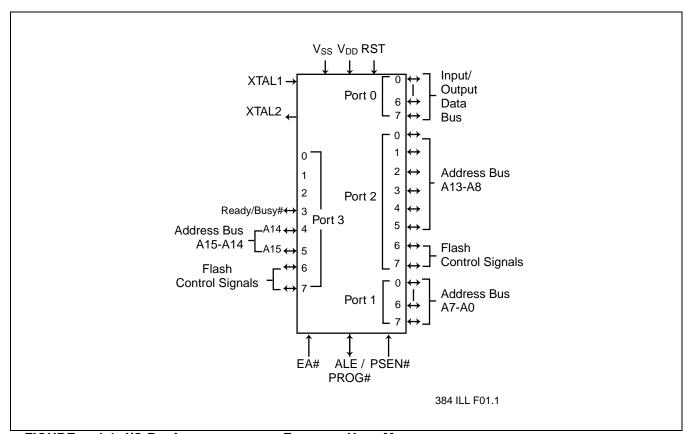


FIGURE 4-1: I/O PIN ASSIGNMENTS FOR EXTERNAL HOST MODE



Preliminary Specifications

4.1.1 Product Identification

The Read-ID command accesses the Signature Bytes that identify the device and the manufacturer as SST. External programmers primarily use these Signature Bytes in the selection of programming algorithms. The Read-ID command is selected by the command code of 0H on P3[7:6] and P2[7:6]. See Figure 4-2 for timing waveforms.

TABLE 4-3: SIGNATURE BYTES

	Address	Data
Manufacturer's ID	30H	BFH
Device ID		
SST89E564	31H	93H
SST89V564	31H	92H
SST89E554	31H	9BH
SST89V554	31H	9AH

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4.1.2 Arming Command

An arming command sequence must take place before any External Host Mode sequence command is recognized by the device. This prevents accidental triggering of External Host Mode Commands due to noise or programmer error. The arming command is as follows:

- 1. PSEN# goes low while RST is high. This will get the machine in External Host Mode, re-configuring the pins, and turning on the on-chip oscillator.
- 2. A Read-ID command is issued, and after 1 ms the External Host Mode commands can be issued.

After the above sequence, all other External Host Mode commands are enabled. Before the Read-ID command is received, all other External Host Mode commands received are ignored.

4.1.3 Detail Explanation of the External Host Mode Commands

The External Host Mode commands are Read-ID, Chip-Erase, Block-Erase, Sector-Erase, Byte-Program, Byte-Verify, Prog-SB1, Prog-SB2, Prog-SB3, Prog-SC0, Prog-SC1, Select-Block0, Select-Block1. See Tables 4-1 and 4-2 for all signal logic assignments, Figure 4-1 for I/O pin assignments, and Table 4-7 for the timing parameters. The critical timing for all Erase and Program commands is generated by an on-chip flash memory controller. The high-to-low transition of the PROG# signal initiates the Erase or Program commands, which are synchronized internally. The Read commands are asynchronous reads, independent of the PROG# signal level.

Following is a detailed description of the External Host Mode commands:

The Select-Block0 command enables Block 0 to be programmed in External Host Mode. Once this command is executed, all subsequent External Host Commands will be directed at Block 0. See Figure 4-3 for timing waveforms. This command applies to SST89E564/SST89V564 only.

The Select-Block1 command enables Block 1 (8 KByte Block) to be programmed. Once this command is executed, all subsequent External Host Commands that are directed to the address range below 2000H will be directed at Block 1. The Select-Block1 command only affects the lowest 8 KByte of the program address space. For addresses greater than or equal to 2000H, Block 0 is accessed by default. Upon entering External Host Mode, Block 1 is selected by default. See Figure 4-3 for timing waveforms. This command applies to SST89E564/SST89V564 only.

The Chip-Erase, Block-Erase, and Sector-Erase commands are used for erasing all or part of the memory array. Erased data bytes in the memory array will be erased to FFH. Memory locations that are to be programmed must be in the erased state prior to programming.

The Chip-Erase command erases all bytes in both memory blocks, regardless of any previous Select-Block0 or Select-Block1 commands. Chip-Erase ignores the Security Lock status and will erase the Security Lock, returning the device to its Unlocked state. The Chip-Erase command will also erase the SC0 bit. Upon completion of Chip-Erase command, Block 1 will be the selected block. See Figure 4-4 for timing waveforms.

The Block-Erase command erases all bytes in the selected memory blocks. This command will not be executed if the security lock is enabled. The selection of the memory block to be erased is determined by the prior execution Select-Block0 or Select-Block1 command. See Figure 4-6 for the timing waveforms.

The Sector-Erase command erases all of the bytes in a sector. The sector size for the flash memory is 128 Bytes. This command will not be executed if the Security lock is enabled. See Figure 4-7 for timing waveforms.

The Byte-Program command is used for programming new data into the memory array. Programming will not take place if any security locks are enabled. See Figure 4-8 for timing waveforms.



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The Byte-Verify command allows the user to verify that the device correctly performed an Erase or Program command. This command will be disabled if any security locks are enabled. See Figure 4-11 for timing waveforms.

The Prog-SB1, Prog-SB2, Prog-SB3 commands program the security bits, the functions of these bits are described in the Security Lock section and also in Table 8-1. Once programmed, these bits can only be erased through a Chip-Erase command. See Figure 4-9 for timing waveforms.

Prog-SC0 command programs SC0 bit, which determines the state of SFCF[0] out of reset. Once programmed, SC0 can only be restored to an erased state via a Chip-Erase command. See Figure 4-10 for timing waveforms.

Prog-SC1 command programs SC1 bit, which determines the state of SFCF[1] out of reset. Once programmed, SC1 can only be restored to an erased state via a Chip-Erase command. See Figure 4-10 for timing waveforms. Prog-SC1 is for SST89E554/SST89V554 only.

4.1.4 External Host Mode Clock Source

In External Host Mode, an internal oscillator will provide clocking for the device. The on-chip oscillator will be turned on as the device enters External Host Mode; i.e. when PSEN# goes low while RST is high. During External Host Mode, the CPU core is held in reset. Upon exit from External Host Mode, the internal oscillator is turned off.

4.1.5 Flash Operation Status Detection Via External Host Handshake

The device provides two methods for an external host to detect the completion of a flash memory operation to optimize the Program or Erase time. The end of a flash memory operation cycle can be detected by:

- 1. monitoring the Ready/Busy# bit at P3[3];
- 2. monitoring the Data# Polling bit at P0[3].

4.1.5.1 Ready/Busy# (P3[3])

The progress of the flash memory programming can be monitored by the Ready/Busy# output signal. P3[3] is driven low, some time after ALE/PROG# goes low during a flash memory operation to indicate the Busy# status of the Flash Control Unit (FCU). P3[3] is driven high when the flash programming operation is completed to indicate the Ready status.

4.1.5.2 Data# Polling (P0[3])

During a Program operation, any attempts to read (Byte-Verify), while the device is busy, will receive the complement of the data of the last byte loaded (logic low, i.e. "0" for an erase) on P0[3] with the rest of the bits "0". During a Program operation, the Byte-Verify command is reading the data of the last byte loaded, not the data at the address specified.

4.1.6 Step-by-step instructions to perform External Host Mode commands

To program data into the memory array, apply power supply voltage (V_{DD}) to V_{DD} and RST pins, and perform the following steps:

- Maintain RST high and set PSEN# from logic high to low, in sequence according to the appropriate timing diagram.
- 2. Raise EA# High (VIH).
- 3. Issue Read-ID command to enable the External Host Mode.
- 4. Verify that the memory blocks or sectors for programming is in the erased state, FFH. If they are not erased, then erase them using the appropriate Erase command.
- 5. Select the memory location using the address lines (P3[5:4], P2[5:0], P1[7:0]).
- 6. Present the data in on P0[7:0].
- 7. Pulse ALE/PROG#, observing minimum pulse width.
- 8. Wait for low to high transition on READY/BUSY# (P3[3]).
- 9. Repeat steps 5 8 until programming is finished.
- 10. Verify the flash memory contents.

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4.1.7 Flash Memory Programming Timing Diagrams with External Host Mode

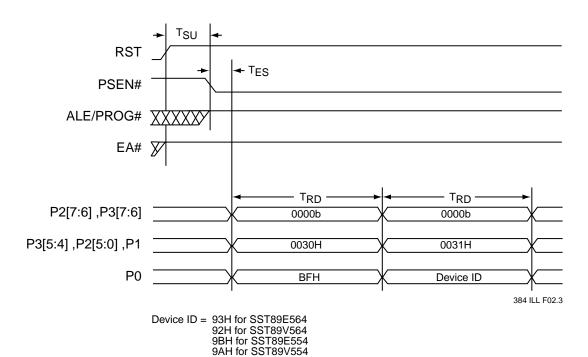


FIGURE 4-2: READ-ID

Reads chip signature and identification registers at the addressed location.

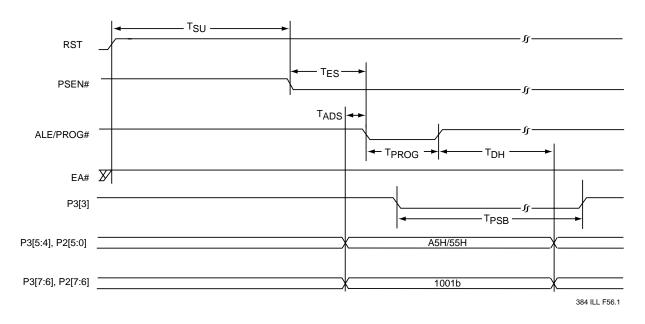


FIGURE 4-3: SELECT-BLOCK1 / SELECT-BLOCK0

Enables the selection of either of the flash memory blocks prior to issuing a Byte-Verify, Block-Erase, Sector-Erase, or Byte-Program. These commands apply to SST89E564/SST89V564 only.



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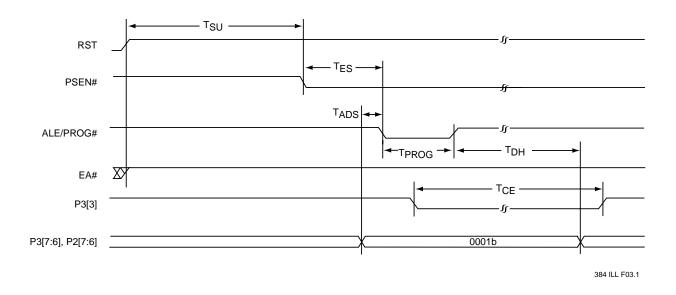


FIGURE 4-4: CHIP-ERASE

Erases both flash memory blocks. Security lock is ignored and the security bits are erased too.

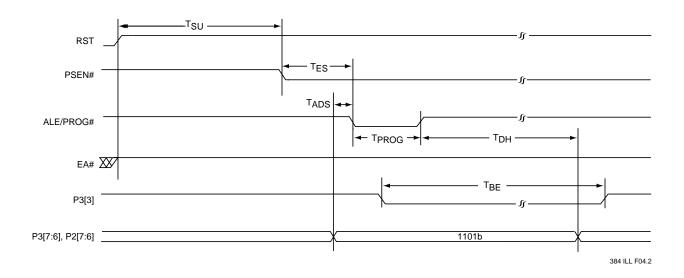


FIGURE 4-5: BLOCK-ERASE FOR SST89E564/SST89V564

Erases one of the flash memory blocks, if the security lock is not activated on that flash memory block.

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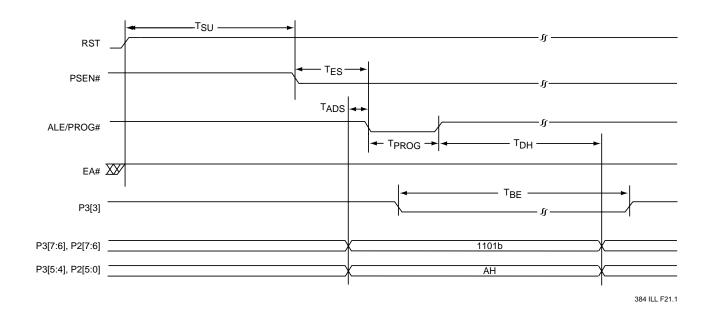


FIGURE 4-6: BLOCK-ERASE FOR SST89E554/SST89V554

Erases one of the flash memory blocks, if the security lock is not activated on that flash memory block.

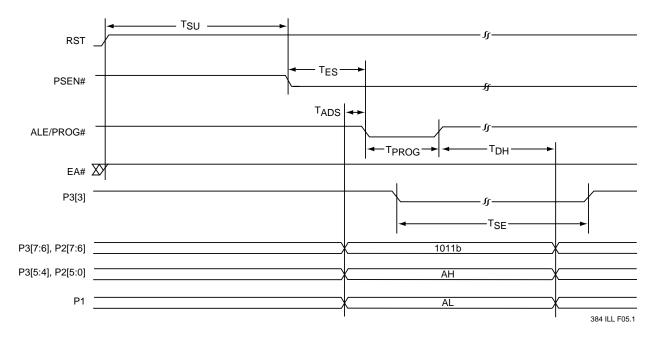


FIGURE 4-7: SECTOR-ERASE

Erases the addressed sector if the security lock is not activated on that flash memory block.



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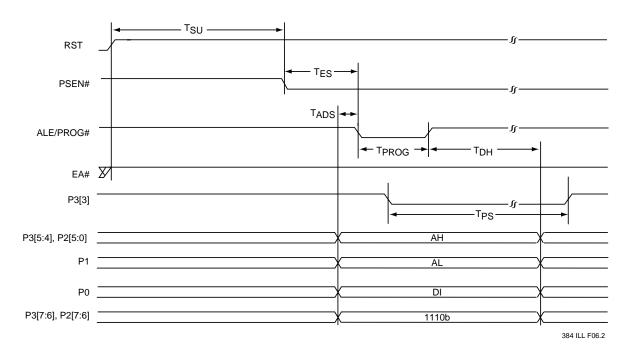


FIGURE 4-8: BYTE-PROGRAM

Programs the addressed code byte if the byte location has been successfully erased and not yet programmed. Byte-Program operation is only allowed when the security lock is not activated on that flash memory block.

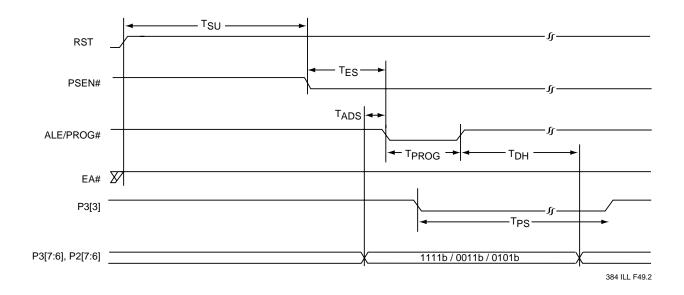


FIGURE 4-9: Prog-SB1 / Prog-SB2 / Prog-SB3

Programs the Security bits SB1, SB2 and SB3 respectively. Only a Chip-Erase will erase a programmed security bit.

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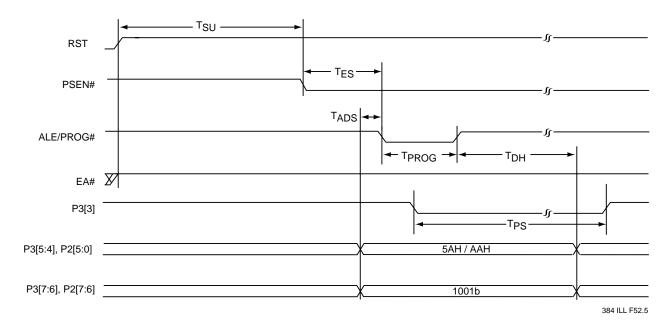


FIGURE 4-10: Prog-SC0 / Prog-SC1

Programs the start-up configuration bit SC0/SC1. Only a Chip-Erase will erase a programmed SC0/SC1 bit. Prog-SC1 applies to SST89E554/SST89V554 only.

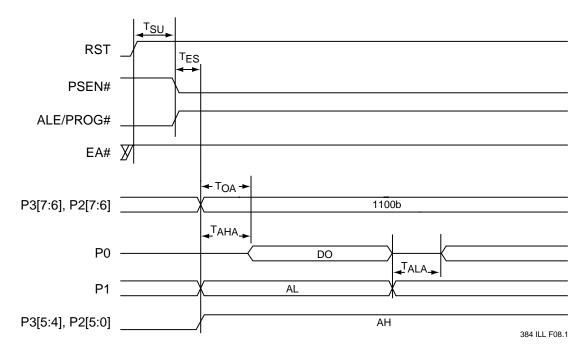


FIGURE 4-11: BYTE-VERIFY

Reads the code byte from the addressed flash memory location if the security lock is not activated on that flash memory block.



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4.2 In-Application Programming Mode

The device offers either 72 or 40 KByte of In-Application Programmable flash memory. During In-Application Programming, the CPU of the microcontroller enters IAP Mode. The two blocks of flash memory allow the CPU to execute user code from one block, while the other is being erased or reprogrammed concurrently. The CPU may also fetch code from an external memory while all internal flash is being reprogrammed. The mailbox registers (SFST, SFCM, SFAL, SFAH, SFDT and SFCF) located in the Special Function Register (SFR), control and monitor the device's erase and program process.

Table 4-6 outlines the commands and their associated mailbox register settings.

4.2.1 In-Application Programming Mode Clock Source

During IAP Mode, both the CPU core and the flash controller unit are driven off the external clock. However, an internal oscillator will provide timing references for Program and Erase operations. The internal oscillator is only turned on when required, and is turned off as soon as the flash operation is completed.

4.2.2 Memory Bank Selection for In-Application Programming Mode

With the addressing range limited to 16 bit, only 64 KByte of program address space is "visible" at any one time. As shown in Table 4-4, Bank Selection (the configuration of EA# and SFCF[1:0]), allows Block 1 memory to be overlaid on the lowest 8 KByte of Block 0 memory, making Block 1 reachable. The same concept is employed to allow both Block 0 and Block 1 flash to be accessible to IAP operations. Code from a block that is not visible may not be used

as a source to program another address. However, a block that is not "visible" may be programmed by code from the other block through mailbox registers.

The device allows IAP code in one block of memory to program the other block of memory, but may not program any location in the same block. If an IAP operation originates physically from Block 0, the target of this operation is implicitly defined to be in Block 1. If the IAP operation originates physically from Block 1, then the target address is implicitly defined to be in Block 0. If the IAP operation originates from External program space, then, the target will depend on the address and the state of Bank Select.

4.2.3 IAP Enable Bit

The IAP Enable Bit, SFCF[6], enables In-Application Programming mode. Until this bit is set all flash programming IAP commands will be ignored.

4.2.4 In-Application Programming Mode Commands

All of the following commands can only be initiated in the IAP Mode. In all situations, writing the control byte to the SFCM register will initiate all of the operations. All commands will not be enabled if the security locks are enabled on the selected memory block.

The Program command is for programming new data into the memory array. The portion of the memory array to be programmed should be in the erased state, FFH. If the memory is not erased, it should first be erased with an appropriate Erase command. Warning: Do not attempt to write (program or erase) to a block that the code is currently fetching from. This will cause unpredictable program behavior and may corrupt program data.

The Block-Erase command erases all bytes in one of the two memory blocks. The selection of the memory block to be erased is determined by the source of Block-Erase Command, as defined in Table 4-4.

TABLE 4-4: IAP ADDRESS RESOLUTION FOR SST89E564/SST89V564

EA#	SFCF[1:0]	Address of IAP Inst.	Target Address	Block Being Programmed	
1	00	>= 2000H (Block 0)	>= 2000H (Block 0)	None ¹	
1	00	>= 2000H (Block 0)	< 2000H (Block 1)	Block 1	
1	00	< 2000H (Block 1)	Any (Block 0)	Block 0	
1	01, 10, 11	Any (Block 0)	>= 2000H (Block 0)	None ¹	
1	01, 10, 11	Any (Block 0)	< 2000H (Block 1)	Block 1	
0	00	From external	>= 2000H (Block 0)	Block 0	
0	0 00 From		< 2000H (Block 1)	Block 1	
0	0 01, 10, 11 Fro		Any (Block 0)	Block 0	

1. No operation is performed because code from one block may not program the same originating block

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The Sector-Erase command erases all of the bytes in a sector. The sector size for the flash memory Blocks is 128 Bytes. The selection of the sector to be erased is determined by the contents of SFAH and SFAL.

The Byte-Program command programs data into a single byte. The address is determined by the contents of SFAH and SFAL. The data byte is in SFDT.

The Byte-Verify command allows the user to verify that the device has correctly performed an Erase or Program command.

Byte-Verify command returns the data byte in SFDT if the command is successful. The user is required to check that the previous flash operation has fully completed before issuing a Byte-Verify. Byte-Verify command execution time is short enough that there is no need to poll for command completion and no interrupt is generated.

Prog-SB3, Prog-SB2, Prog-SB1 commands are used to program the Security bits (see Table 8-1). Completion of any of these commands, the security options will be updated immediately.

Security bits previously in un-programmed state can be programmed by these commands. Prog-SB3, Prog-SB2 and Prog-SB1 commands should only reside in Block 1.

Prog-SC0 command is used to program the SC0 bit. This command only changes the SC0 bit and has no effect on BSEL bit until after a reset cycle.

SC0 bit previously in un-programmed state can be programmed by this command. The Prog-SC0 command should reside only in Block 1.

Prog-SC1 command is used to program the SC1 bit. This command only changes the SC1 bit and has no effect on BSEL bit until after a reset cycle.

SC1 bit previously in un-programmed state can be programmed by this command. The Prog-SC1 command should reside only in Block 1.

There are no IAP counterparts for the External Host commands Select-Block0 and Select-Block1.

4.2.5 Polling

A command that uses the polling method to detect flash operation completion should poll on the FLASH_BUSY bit (SFST[2]). When FLASH_BUSY de-asserts (logic 0), the device is ready for the next operation.

MOVC instruction may also be used for verification of the Programming and Erase operation of the flash memory. MOVC instruction will fail if it is directed at a flash block that is still busy.

4.2.6 Interrupt Termination

If interrupt termination is selected, (SFCM[7] is set), then an interrupt (INT1) will be generated to indicate flash operation completion. Under this condition, the INT1 becomes an internal interrupt source. The INT1# pin can now be used as a general purpose port pin and it cannot be the source of External Interrupt 1 during In-Application Programming.

In order to use an interrupt to signal flash operation termination. EX1 and EA bits of IE register must be set. The IT1 bit of TCON register must also be set for edge trigger detection.

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TABLE 4-5: In-Application Programming Mode Commands¹ for SST89E564/SST89V564

Operation	SFCM [6:0] ²	SFDT [7:0]	SFAH [7:0]	SFAL [7:0]
Block-Erase ³	0DH	55H	X ⁴	X
Sector-Erase ³	0BH	X	AH ⁵	AL ⁶
Byte-Program ³	0EH	DI ⁷	AH	AL
Byte-Verify (Read) ³	0CH	DO ⁸	AH	AL
Prog-SB1 ⁹	0FH	AAH	X	X
Prog-SB2 ⁹	03H	AAH	X	X
Prog-SB3 ⁹	05H	AAH	X	X
Prog-SC0 ⁹	09H	AAH	5AH	X

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- 1. SFCF[6]=1 enables IAP commands; SFCF[6]=0 disables IAP commands.
- Interrupt/Polling enable for flash operation completion
 SFCM[7] = 1: Interrupt enable for flash operation completion
 0: polling enable for flash operation completion
- 3. Refer to Table 4-4 for address resolution
- 4. X can be V_{IL} or V_{IH}, but no other value.
- 5. AH = Address high order byte
- 6. AL = Address low order byte
- 7. DI = Data Input
- 8. DO = Data Output
 All other values are in hex
- 9. Instruction must be located in Block 1

TABLE 4-6: In-Application Programming Mode Commands¹ for SST89E554/SST89V554

Operation	SFCM [6:0] ²	SFDT [7:0]	SFAH [7:0]	SFAL [7:0]
Block-Erase ³	0DH	55H	AH ⁴	X ⁵
Sector-Erase ³	0BH	X	AH ⁶	AL ⁷
Byte-Program ³	0EH	DI ⁸	AH	AL
Byte-Verify (Read) ³	0CH	DO ⁹	AH	AL
Prog-SB1 ¹⁰	0FH	AAH	X	X
Prog-SB2 ¹⁰	03H	AAH	X	X
Prog-SB3 ¹⁰	05H	AAH	X	X
Prog-SC0 ¹⁰	09H	AAH	5AH	X
Prog-SC1 ¹⁰	09H	AAH	AAH	X

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- 1. SFCF[6]=1 enables IAP commands; SFCF[6]=0 disables IAP commands.
- Interrupt/Polling enable for flash operation completion SFCM[7] = 1: Interrupt enable for flash operation completion
 - 0: polling enable for flash operation completion
- 3. Refer to Table 4-4 for address resolution
- 4. SFAH[7]=0: Selects Block 0; SFAH[7:5] = 111b selects Block 1
- 5. X can be V_{IL} or V_{IH} , but no other value.
- 6. AH = Address high order byte
- 7. AL = Address low order byte
- 8. DI = Data Input
- 9. DO = Data Output
 All other values are in hex
- 10. Instruction must be located in Block 1

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TABLE 4-7: FLASH MEMORY PROGRAMMING/VERIFICATION PARAMETERS

Parameter ^{1,2}	Symbol	Min	Max	Units
Reset Setup Time	T _{SU}	3		μs
Read-ID Command Width	T _{RD}	1		μs
PSEN# Setup Time	T _{ES}	1.125		μs
Address, Command, Data Setup Time	T _{ADS}	0		ns
Chip-Erase Time	T _{CE}		125	ms
Block-Erase Time	T _{BE}		100	ms
Sector-Erase Time	T _{SE}		30	ms
Program Setup Time	T_{PROG}	1.2		μs
Address, Command, Data Hold	T_DH	0		ns
Byte-Program Time ³	T _{PB}		50	μs
Select-Block Program Time	T _{PSB}		500	ns
Security bit Program Time	T _{PS}		80	μs
Verify Command Delay Time	T _{OA}		50	ns
Verify High Order Address Delay Time	T _{AHA}		50	ns
Verify Low Order Address Delay Time	T _{ALA}		50	ns

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- 1. Program and Erase times will scale inversely proportional to programming clock frequency.
- 2. All timing measurements are from the 50% of the input to 50% of the output.
- 3. Each byte must be erased before programming.

5.0 TIMERS/COUNTERS

The device has three 16-bit registers that can be used as either timers or event counters. The three Timers/Counters are denoted Timer 0 (T0), Timer 1 (T1), and Timer 2 (T2). Each is designated a pair of 8-bit registers in the SFRs. The pair consists of a most significant (high) byte and least significant (low) byte. The respective registers are TL0, TH0, TL1, TH1, TL2, and TH2.

6.0 SERIAL I/O

6.1 Enhanced Universal Aysnchronous Receiver/Transmitter (UART)

The device Serial I/O port is a full duplex port that allows data to be transmitted and received simultaneously in hardware by the transmit and receive registers, respectively, while the software is performing other tasks. The transmit and receive registers are both located in the Serial Data Buffer (SBUF) special function register. Writing to the SBUF register loads the transmit register, and reading from the SBUF register obtains the contents of the receive register.

The UART has four modes of operation which are selected by the Serial Port Mode Specifier (SM0 and SM1) bits of the Serial Port Control (SCON) special function register. In all four modes, transmission is initiated by any instruction that uses the SBUF register as a destination register. Reception is initiated in mode 0 when the Receive Interrupt (RI) flag bit of the Serial Port Control (SCON) SFR is cleared and the Reception Enable/ Disable (REN) bit of the SCON register is set. Reception is initiated in the other modes by the incoming start bit if the REN bit of the SCON register is set.

6.1.1 Framing Error Detection

Framing Error Detection allows the serial port to automatically check for valid stop bits in Modes 1, 2 or 3. If a stop bit is missing the Framing Error bit (FE) will be set. The software can then check this bit after a reception to detect communication errors. The FE bit must be cleared by software.

The FE bit is located in SCON and shares the same bit address as SM0. The SMOD0 bit located in the PCON register determines which of these two bits is accessed. When SMOD0 = 0, SCON[7] will act as SMO. When SMOD0 = 1, SCON[7] will act as FE.

6.1.2 Automatic Address Recognition

Automatic Address Recognition (AAR) reduces the CPU time required to service the serial port in a multiprocessor environment. When using AAR, the serial port hardware will only generate an interrupt when it receives its own address, thus eliminating the software overhead required to compare addresses.



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AAR is only available when using the serial port in either mode 2 or 3. Setting the SM2 bit in SCON enables AAR. Each slave must have its SM2 bit set when waiting for an address (9th bit = 1). The Receive Interrupt (RI) flag will only be set when the received byte matches either the Given or Broadcast Address. The slave then clears its SM2 bit to enable reception of data bytes (9th bit = 0) from the master.

The master can selectively communicate with groups of slaves by sending the Given Address. Addressing all slaves is also possible by sending the Broadcast address. The SADDR and SADEN special function registers define these addresses for each slave.

SADDR specifies a slaves individual address and SADEN is a mask byte that defines don't-care bits to form the Given address when combined with SADDR. The following is an example:

	UART Slave 1	
SADDR	=	1111 0001
SADEN	=	1111 1010
GIVEN	=	1111 0x0x

	UART Slave 2	
SADDR	=	1111 0011
SADEN	=	1111 1001
GIVEN	=	1111 0xx1

In this example Slave 1 can be distinguished from Slave 2 by using bits 0 and 1. Slave 1 will not respond to an address that has bit 1 set to 1 while Slave 2 will. Similarly,

Slave 2 will not respond to an address that has bit 0 set to 0 while Slave 1 will. Both slaves will respond to an address of 1111 0x01b so this is the Broadcast Address. The Broadcast Addresses is formed by the logical OR of SADDR and SADEN with 0s treated as don't-care bits.

6.2 Serial Peripheral Interface (SPI)

The device SPI allows for high-speed full-duplex synchronous data transfer between the device and other compatible SPI devices.

Figure 6-1 shows the correspondence between master and slave SPI devices. The SCK pin is the clock output and input for the master and slave modes, respectively. The SPI clock generator will start following a write to the master devices SPI data register. The written data is then shifted out of the MOSI pin on the master device into the MOSI pin of the slave device. Following a complete transmission of one byte of data, the SPI clock generator is stopped and the SPIF flag is set. An SPI interrupt request will be generated if the SPI interrupt enable bit (SPIE) and the serial port interrupt enable bit (ES) are both set.

An external master drives the Slave Select input pin, SS#/P1[4], low to select the SPI module as a slave. If SS#/P1[4] has not been driven low, then the slave SPI unit is not active and the MOSI/P1[5] port can also be used as an input port pin.

CPHA and CPOL control the phase and polarity of the SPI clock. Figures 6-2 and 6-3 show the four possible combinations of these two bits.

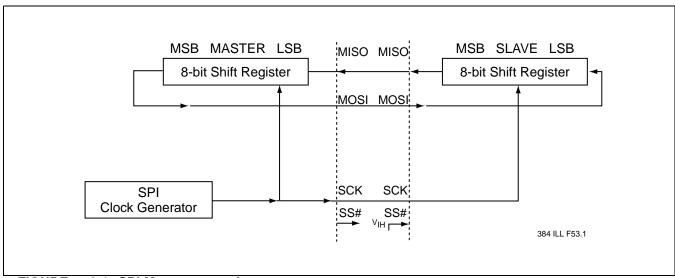
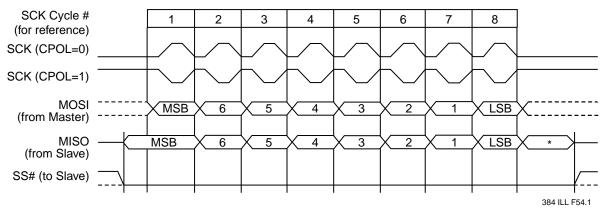


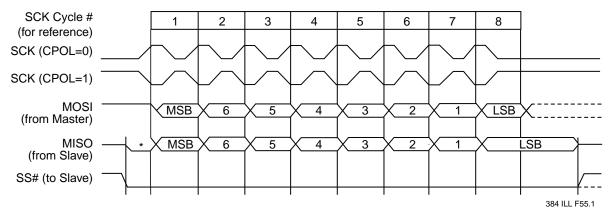
FIGURE 6-1: SPI MASTER-SLAVE INTERCONNECTION

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^{*} Not defined, but normally MSB of next received byte

FIGURE 6-2: SPI TRANSFER FORMAT WITH CPHA = 0



^{*} Not defined but normally LSB of previously transmitted character

FIGURE 6-3: SPI TRANSFER FORMAT WITH CPHA = 1



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7.0 WATCHDOG TIMER

The device offers a programmable Watchdog Timer (WDT) for fail safe protection against software deadlock and automatic recovery.

To protect the system against software deadlock, the user software must refresh the WDT within a user-defined time period. If the software fails to do this periodical refresh, an internal hardware reset will be initiated if enabled (WDRE= 1). The software can be designed such that the WDT times out if the program does not work properly.

The WDT in the device uses the system clock (XTAL1) as its time base. So strictly speaking, it is a watchdog counter rather than a watchdog timer. The WDT register will increment every 344064 crystal clocks. The upper 8-bits of the time base register (WDTD) are used as the reload register of the WDT.

The WDTS flag bit is set by WDT overflow and is not changed by WDT reset. User software can clear WDTS by writing "1" to it.

Figure 7-1 provides a block diagram of the WDT. Two SFRs (WDTC and WDTD) control watchdog timer operation. During idle mode, WDT operation is temporarily suspended, and resumes upon an interrupt exit from idle.

The time-out period of the WDT is calculated as follows:

where WDT is the value loaded into the WDT register and f_{OSC} is the oscillator frequency.

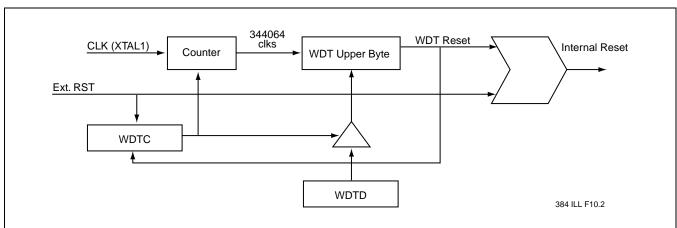


FIGURE 7-1: BLOCK DIAGRAM OF PROGRAMMABLE WATCHDOG TIMER

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8.0 SECURITY LOCK

The Security Lock protects against software piracy and prevents the contents of the flash from being read by unauthorized parties. It also protects against code corruption resulting from accidental erasing and programming to the internal flash memory. There are two different types of security locks in the device security lock system: Hard Lock and SoftLock.

8.1 Hard Lock

When Hard Lock is activated, MOVC or IAP instructions executed from an unlocked or SoftLocked program address space, are disabled from reading code bytes in Hard Locked memory blocks (See Table 8-2). Hard Lock can either lock both flash memory blocks or just lock the 8 KByte flash memory block (Block 1). All External Host and IAP commands except for Chip-Erase are ignored for memory blocks that are Hard Locked.

8.2 SoftLock

SoftLock allows flash contents to be altered under a secure environment. This lock option allows the user to update program code in the SoftLocked memory block through In-Application Programming Mode under a predetermined secure environment. For example, if Block 1 (8K) memory block is locked (Hard Locked or SoftLocked), and Block 0 (64K for SST89E564/SST89V564) memory block is SoftLocked, code residing in Block 1 can program Block 0. The following IAP mode commands issued through the com-

mand mailbox register, SFCM, executed from a Locked (Hard Locked or SoftLocked) block, can be operated on a SoftLocked block: Block-Erase, Sector-Erase, Byte-Program and Byte-Verify.

In External Host Mode, SoftLock behaves the same as a Hard Lock.

8.3 Security Lock Status

The three bits that indicate the device security lock status are located in SFST[7:5]. As shown in Figure 8-1 and Table 8-1, the three security lock bits control the lock status of the primary and secondary blocks of memory. There are four distinct levels of security lock status. In the first level, none of the security lock bits are programmed and both blocks are unlocked. In the second level, although both blocks are now locked and cannot be programmed, they are available for read operation via Byte-Verify. In the third level, three different options are available: Block 1 Hard Lock / Block 0 SoftLock, SoftLock on both blocks, and Hard Lock on both blocks. Locking both blocks is the same as Level 2 except read operation isn't available. The fourth level of security is the most secure level. It doesn't allow read/program of internal memory or boot from external memory. Please note that for unused combinations of the security lock bits, the chip will default to Level 4 status. For details on how to program the security lock bits refer to the External Host Mode and In-Application Programming Section.

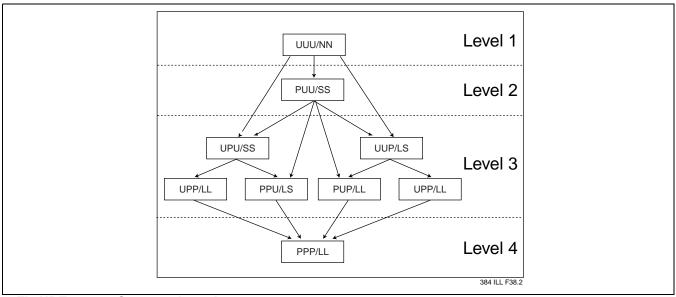


FIGURE 8-1: SECURITY LOCK LEVELS

Notes: P = Programmed (Cell logic state = 0), U = Unprogrammed (Cell logic state = 1), N = Not Locked, L = Hard Locked, S = SoftLocked.



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TABLE 8-1: SECURITY LOCK OPTIONS

	Se	curity Lo	ck Bits ^{1,2}		Security	Status of:	
Level	SFST[7:5]	SB1	SB2 ¹	SB3 ¹	Block 1	Block 0	Security Type
1	000	U	U	U	Unlock	Unlock	No Security Features are Enabled.
2	100	Р	U	U	SoftLock	SoftLock	MOVC instructions executed from external program memory are disabled from fetching code bytes from internal memory, EA# is sampled and latched on Reset, and further programming of the flash is disabled.
3	011 101	U P	P U	P P	Hard Lock	Hard Lock	Level 2 plus Verify disabled, both blocks locked.
	010	U	Р	U	SoftLock	SoftLock	Level 2 plus Verify disabled. Code in Block 1 may program Block 0 and vice versa.
	110 001	P U	P U	U P	Hard Lock	SoftLock	Level 2 plus Verify disabled. Code in Block 1 may program Block 0.
4	111	Р	Р	Р	Hard Lock	Hard Lock	Same as Level 3 Hardlock/Hardlock, but MCU will start code execution from the internal memory regardless of EA#.

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P = Programmed (Cell logic state = 0), U = Unprogrammed (Cell logic state = 1).
 SFST[7:5] = Security Lock Decoding Bits (SECD)



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TABLE 8-2: SECURITY LOCK ACCESS TABLE

Level	SFST[7:5]	Source Address	Target Address ¹	External Host Byte-Verify Allowed ²	IAP Byte-Verify Allowed	MOVC Allowed on 564	MOVC Allowed on 554
		DI 1.0/4	Block 0/1	N	N	Υ	Υ
	111b	Block 0/1	External	N/A	N	N	N
4	(Hard Lock on both blocks)	Estemal	Block 0/1	N	N	N	N
		External	External	N/A	N	N	N
		Dia als 0/4	Block 0/1	N	N	Υ	Υ
	011b/101b	Block 0/1	External	N	N	N	Υ
	(Hard Lock on both blocks)	Estemal	Block 0/1	N	N	N	N
		External	External	N/A	N	Y	Y
			Block 0	N	N	Υ	Υ
		Block 0	Block 1	N	N	N	N
			External	N/A	N	N	Υ
	001b/110b		Block 0	N	Y	Y	Υ
(Block 0 = SoftLock, Block 1 = Hard Lock	Block 1	Block 1	N	N	Υ	Y	
2	3		External	N/A	N	N	Y
3		F. d	Block 0/1	N	N	N	N
		External	External	N/A	N	Y	Υ
			Block 0	N	N	Υ	Υ
	010b (SoftLock on both blocks)	Block 0	Block 1	N	Υ	Υ	Υ
			External	N/A	N	N	Υ
		Block 1	Block 0	N	Υ	Υ	Υ
			Block 1	N	N	Υ	Υ
			External	N/A	N	N	Y
		Estemal	Block 0/1	N	N	N	N
		External	External	N/A	N	Υ	Υ
			Block 0	Y	N	Y	Υ
		Block 0	Block 1	Y	Υ	Υ	Υ
			External	N/A	N	N	Υ
0	100b		Block 0	Y	Y	Y	Y
2	(SoftLock on both blocks)	Block 1	Block 1	Y	N	Υ	Υ
			External	N/A	N	N	Υ
		Ft 1	Block 0/1	Y	N	N	N
		External	External	N/A	N	Υ	Υ
			Block 0	Y	N	Υ	Υ
		Block 0	Block 1	Y	Y	Y	Y
			External	N/A	N	N	Y
4	000b		Block 0	Y	Y	Υ	Y
1	(Unlock)	Block 1	Block 1	Y	N	Υ	Υ
·			External	N/A	N	N	Y
		F	Block 0/1	Y	Y	N	Y
		External	External	N/A	N	Υ	Υ
4 1 4	ocation of MOVC instruction			1		1	T8-2.1 384

1. Location of MOVC instruction

2. External Host Byte-Verify access does not depend on a source address.

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9.0 RESET

A system reset initializes the MCU and begins program execution at program memory location 0000H. The reset input for the device is the RST pin. In order to reset the device, a logic level high must be applied to the RST pin for at least two machine cycles (24 clocks), after the oscillator becomes stable. ALE, PSEN# are weakly pulled high during reset. During reset, ALE and PSEN# output a high level in order to perform a proper reset. This level must not be affected by external element. A system reset will not affect the 1 KByte of on-chip RAM while the device is running, however, the contents of the on-chip RAM during power up are indeterminate. Following reset, all Special Function Registers (SFR) return to their reset values outlined in Tables 3-5 to 3-9.

9.1 Power-On Reset

At initial power up, the port pins will be in a random state until the oscillator has started and the internal reset algorithm has weakly pulled all pins high. Powering up the device without a valid reset could cause the MCU to start executing instructions from an indeterminate location. Such undefined states may inadvertently corrupt the code in the flash.

When power is applied to the device, the RST pin must be held high long enough for the oscillator to start up (usually several milliseconds for a low frequency crystal), in addition to two machine cycles for a valid Power-On Reset. An example of a method to extend the RST signal is to implement a RC circuit by connecting the RST pin to V_{DD} through a 10 μF capacitor and to V_{SS} through an $8.2 \mbox{K}\Omega$ resistor as shown in Figure 9-1. Note that if an RC circuit is being used, provisions should be made to ensure the V_{DD} rise time does not exceed 1 millisecond and the oscillator start-up time does not exceed 10 milliseconds.

For a low frequency oscillator with slow start-up time the reset signal must be extended in order to account for the slow start-up time. This method maintains the necessary relationship between V_{DD} and RST to avoid programming at an indeterminate location, which may cause corruption in the code of the flash. For more information on system level design techniques, please review Design Considerations for the SST FlashFlex51 Family Microcontroller Application Note.

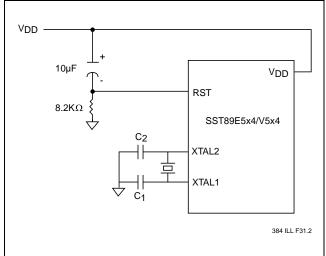


FIGURE 9-1: POWER-ON RESET CIRCUIT

9.2 Software Reset

The software reset is executed by changing SFCF[1] (SWR) from "0" to "1". A software reset will reset the program counter to address 0000H. All SFR registers will be set to their reset values, except SFCF[1] (SWR), WDTC[2] (WDTS), and RAM data will not be altered.

9.3 Brown-out Detection Reset

The device includes a Brown-out detection circuit to protect the system from severe V_{DD} fluctuations. For Brown-out voltage parameters, please refer to Tables 10-3 and 10-4.

Brown-out interrupt can be enabled by setting the EBO bit in IEA register (address E8H, bit 3). If EBO bit is set and a Brown-out condition occurs, a Brown-out interrupt will be generated to execute the program at location 004BH. It is required that the EBO bit be cleared by software after the Brown-out interrupt is serviced. Clearing EBO bit when the Brown-out condition is active will properly reset the device.

If Brown-out interrupt is not enabled, a Brown-out condition will reset the program to resume execution at location 0000H.

9.4 Interrupt Priority and Polling Sequence

The device supports eight interrupt sources under a four level priority scheme. Table 9-1 summarizes the polling sequence of the supported interrupts. Note that the SPI serial interface and the UART share the same interrupt vector.



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TABLE 9-1: INTERRUPT POLLING SEQUENCE

Description	Interrupt Flag	Vector Address	Interrupt Enable	Interrupt Priority	Arbitration Ranking	Wake-Up Power Down
Ext. Int0	IE0	0003H	EX0	PX0/H	1(highest)	yes
Brown-out	BOF	004BH	EBO	PBO/H	2	no
T0	TF0	000BH	ET0	PT0/H	3	no
Ext. Int1	IE1	0013H	EX1	PX1/H	4	yes
T1	TF1	001BH	ET1	PT1/H	5	no
UART/SPI	TI/RI/SPIF	0023H	ES	PS/H	6	no
T2	TF2, EXF2	002BH	ET2	PT2/H	7	no

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9.5 Power-Saving Modes

The device provides three power saving modes of operation for applications where power consumption is critical. The three power saving modes are: Idle, Power Down and Standby (Stop Clock).

9.5.1 Idle Mode

Idle mode is entered setting the IDL bit in the PCON register. In Idle mode, the program counter (PC) is stopped. The system clock continues to run and all interrupts and peripherals remain active. The on-chip RAM and the special function registers hold their data during this mode.

The device exits Idle mode through either a system interrupt or a hardware reset. Exiting Idle mode via system interrupt, the start of the interrupt clears the IDL bit and exits Idle mode. After exit the Interrupt Service Routine, the interrupted program resumes execution beginning at the instruction immediately following the instruction which invoked the Idle mode. A hardware reset starts the device similar to a power-on reset.

9.5.2 Power Down Mode

The Power Down mode is entered by setting the PD bit in the PCON register. In the Power Down mode, the clock is stopped and external interrupts are active for level sensitive interrupts only. To retain the on-chip RAM and all of the special function registers' values, the minimum V_{DD} level is 2.0V.

The device exits Power Down mode through either an enabled external level sensitive interrupt or a hardware reset. The start of the interrupt clears the PD bit and exits Power Down. Holding the external interrupt pin low restarts the oscillator, the signal must hold low at least 1024 clock cycles before bringing back high to complete the exit. After exit the interrupt service routine program execution resumes beginning at the instruction immediately following the instruction which invoked Power Down mode. A hardware reset starts the device similar to power-on reset.

To exit properly out of Power Down, the reset or external interrupt should not be executed before the V_{DD} line is restored to its normal operating voltage. Be sure to hold V_{DD} voltage long enough at its normal operating level for the oscillator to restart and stabilize (normally less than 10 ms).

9.5.3 Standby Mode (Stop Clock)

Standby mode is similar to Power Down mode, except that Power Down mode is initiated by a software command and Standby mode is initiated by external hardware gating off the external clock to the device. The on-chip SRAM and SFR data are maintained in Standby mode. The device resumes operation at the next instruction when the clock is reapplied to the part.

Table 9-2 outlines the different power-saving modes, including entry and exit procedures and MCU functionality.



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TABLE 9-2: Power Saving Modes

Mode	Initiated by	State of MCU	Exited by
Idle Mode	Software (Set IDL bit in PCON)	CLK is running. Interrupts, serial port and timers/counters are active. Program Counter is stopped. ALE and PSEN# signals at a HIGH level during Idle. All registers remain unchanged.	Enabled interrupt or hardware reset. Start of interrupt clears IDL bit and exits Idle mode, after the ISR RETI instruction, program resumes execution beginning at the instruction following the one that invoked Idle mode. A user could consider placing two or three NOP instructions after the instruction that invokes idle mode to eliminate any problems. A hardware reset restarts the device similar to a power-on reset.
Power Down Mode	Software (Set PD bit in PCON)	CLK is stopped. On-chip SRAM and SFR data is main- tained. ALE and PSEN# sig- nals at a LOW level during Power Down. External Inter- rupts are only active for level sensitive interrupts, if enabled.	Enabled external level sensitive interrupt or hardware reset. Start of interrupt clears PD bit and exits Power Down mode, after the ISR RETI instruction program resumes execution beginning at the instruction following the one that invoked Power Down mode. A user could consider placing two or three NOP instructions after the instruction that invokes Power Down mode to eliminate any problems. A hardware reset restarts the device similar to a power-on reset.
Standby (Stop Clock) Mode	External hardware gates OFF the external clock input to the MCU. This gating should be synchronized with an input clock transition (low-to-high or high-to-low).	CLK is frozen. On-chip SRAM and SFR data is maintained. ALE and PSEN# are maintained at the levels prior to the clock being frozen.	Gate ON external clock. Program execution resumes at the instruction following the one during which the clock was gated off.

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9.6 Clock Input Options

Shown in Figure 9-2 are the input and output of an internal inverting amplifier (XTAL1, XTAL2), which can be configured for use as an on-chip oscillator.

When driving the device from an external clock source, XTAL2 should be left disconnected and XTAL1 should be driven.

At start-up, the external oscillator may encounter a higher capacitive load at XTAL1 due to interaction between the amplifier and its feedback capacitance. However, the capacitance will not exceed 15 pF once the external signal meets the $V_{\rm IL}$ and $V_{\rm IH}$ specifications.

9.7 Recommended Capacitor Values for Crystal Oscillator

Crystal manufacturer, supply voltage, and other factors may cause circuit performance to differ from one application to another. C1 and C2 should be adjusted appropriately for each design. The table below, shows the typical values for C1 and C2 at a given frequency. If following the satisfactory selection of all external components, the circuit is still over driven, a series resistor, Rs, may be added.

RECOMMENDED VALUES FOR CRYSTAL OSCILLATOR

Frequency	C1 and C2	R _S (Optional)
< 8MHz	90-110pF	100Ω
8-12MHz	18-22pF	200Ω
>12MHz	18-22pF	200Ω

More specific information about on-chip oscillator design can be found in *FlashFlex 51 Oscillator Circuit Design Considerations* Application Note.

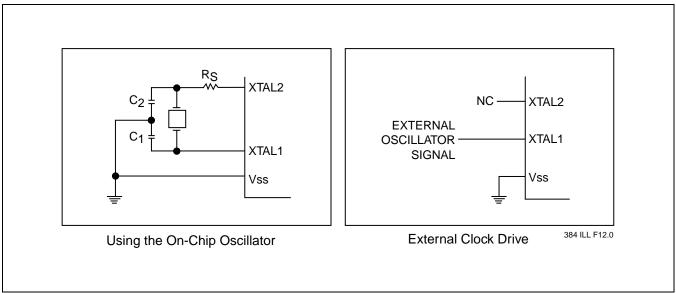


FIGURE 9-2: OSCILLATOR CHARACTERISTICS



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10.0 ELECTRICAL SPECIFICATION

Absolute Maximum Stress Ratings (Applied conditions greater than those listed under "Absolute Maximum Stress Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these conditions or conditions greater than those defined in the operational sections of this data sheet is not implied. Exposure to absolute maximum stress rating conditions may affect device reliability.)

Ambient Temperature Under Bias	55°C to +125°C
Storage Temperature	65°C to + 150°C
Voltage on EA# Pin to V _{SS}	0.5V to +14.0V
Transient Voltage (<20ns) on Any Other Pin to V _{SS}	1.0V to +6.5V
Maximum I _{OL} per I/O Pins P1.5, P1.6, P1.7	20mA
Maximum I _{OL} per I/O for All Other Pins	
Package Power Dissipation Capability (T _a = 25°C)	1.5W
Through Hole Lead Soldering Temperature (10 Seconds)	300°C
Surface Mount Lead Soldering Temperature (3 Seconds)	240°C
Output Short Circuit Current ¹	50 mA

Outputs shorted for no more than one second. No more than one output shorted at a time.
 (Based on package heat transfer limitations, not device power consumption.

Note: This specification contains preliminary information on new products in production. The specifications are subject to change without notice.

10.1 Operation Range

TABLE 10-1: OPERATING RANGE

Symbol	Description	Min.	Max	Unit
Ta	Ambient Temperature Under Bias			
	Standard	0	+70	°C
	Industrial	-40	+85	°C
V_{DD}	Supply Voltage	2.7	5.5	V
fosc	Oscillator Frequency	0	40	MHz
	For In-Application Programming	0.25	40	MHz

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10.2 Reliability Characteristics

TABLE 10-2: RELIABILITY CHARACTERISTICS

Symbol	Parameter	Minimum Specification	Units	Test Method
N _{END} ¹	Endurance	10,000	Cycles	JEDEC Standard A117
T _{DR} ¹	Data Retention	100	Years	JEDEC Standard A103
I _{LTH} ¹	Latch Up	100 + I _{DD}	mA	JEDEC Standard 78

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^{1.} This parameter is measured only for initial qualification and after a design or process change that could affect this parameter.



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10.3 DC Electrical Characteristics

TABLE 10-3: DC ELECTRICAL CHARACTERISTICS $T_{amb} = 0^{\circ}C \text{ To } +70^{\circ}C \text{ or } -40^{\circ}C \text{ To } +85^{\circ}C, 40\text{MHz devices; } 4.5-5.5\text{V}; \text{ V}_{SS} = 0\text{V}$

Symbol	Parameter	Test Conditions	Min	Max	Units
V _{IL}	Input Low Voltage	4.5 < V _{DD} < 5.5	-0.5	0.2V _{DD} - 0.1	V
V _{IH}	Input High Voltage	4.5 < V _{DD} < 5.5	$0.2V_{DD} + 0.9$	V _{DD} + 0.5	V
V _{IH1}	Input High Voltage (XTAL1, RST)	4.5 < V _{DD} < 5.5	0.7V _{DD}	V _{DD} + 0.5	V
V _{OL}	Output Low Voltage (Ports 1.5, 1.6, 1.7)	$V_{DD} = 4.5V$			
		$I_{OL} = 16mA$		1.0	V
V _{OL}	Output Low Voltage (Ports 1, 2, 3) ¹	$V_{DD} = 4.5V$			
		$I_{OL} = 100 \mu A^2$		0.3	V
		$I_{OL} = 1.6 \text{mA}^2$		0.45	V
		$I_{OL} = 3.5 \text{mA}^2$		1.0	V
V _{OL1}	Output Low Voltage (Port 0, ALE, PSEN#) ^{1,3}	$V_{DD} = 4.5V$			
		$I_{OL} = 200 \mu A^2$		0.3	V
		$I_{OL} = 3.2 \text{mA}^2$		0.45	V
V _{OH}	Output High Voltage (Ports 1, 2, 3, ALE, PSEN#) ⁴	$V_{DD} = 4.5V$			
		I _{OH} = -10μA	V _{DD} - 0.3		V
		I _{OH} = -30μA	V _{DD} - 0.7		V
		I _{OH} = -60μA	V _{DD} - 1.5		V
V _{OH1}	Output High Voltage (Port 0 in External Bus Mode) ⁴	$V_{DD} = 4.5V$			
		$I_{OH} = -200 \mu A$	V _{DD} - 0.3		V
		$I_{OH} = -3.2 \text{mA}$	V _{DD} - 0.7		V
V_{BOD}	Brown-out Detection Voltage		3.85	4.15	V
I _{IL}	Logical 0 Input Current (Ports 1, 2, 3)	$V_{IN} = 0.4V$	-1	-75	μΑ
I _{TL}	Logical 1-to-0 Transition Current (Ports 1, 2, 3) ⁵	$V_{IN} = 2V$		-650	μΑ
ILI	Input Leakage Current (Port 0)	$0.45 < V_{IN} < V_{DD}$ -0.3		±10	μΑ
R _{RST}	RST Pulldown Resistor		40	225	kΩ
C _{IO}	Pin Capacitance ⁶	@ 1 MHz, 25°C		15	pF
I_{DD}	Power Supply Current ⁷				
	In-Application Mode				
	@ 20 MHz			70	mA
	@ 40 MHz			88	mA
	Active Mode				
	@ 20 MHz			25	mA
	@ 40 MHz			45	mA
	Idle Mode				
	@ 20 MHz			9.5	mA
	@ 40 MHz			20	mA
	Standby (Stop Clock) Mode	$T_{amb} = 0$ °C to +70°C		100	μΑ
		$T_{amb} = -40$ °C to +85°C		125	μA
	Power Down Mode	Minimum $V_{DD} = 2V$			
		$T_{amb} = 0$ °C to +70°C		40	μΑ
		$T_{amb} = -40^{\circ}C \text{ to } +85^{\circ}C$		50	μΑ

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TABLE 10-4: DC ELECTRICAL CHARACTERISTICS $T_{amb} = 0^{\circ}\text{C to } +70^{\circ}\text{C or } -40^{\circ}\text{C to } +85^{\circ}\text{C}, 25\text{MHz devices; 2.7-3.6V; V}_{SS} = 0\text{V}$

Symbol	Parameter	Test Conditions	Min	Max	Units
V _{IL}	Input Low Voltage	2.7 < V _{DD} < 3.3	-0.5	0.7	V
V_{IH}	Input High Voltage	$2.7 < V_{DD} < 3.3$	$0.2V_{DD} + 0.9$	$V_{DD} + 0.5$	V
V _{IH1}	Input High Voltage (XTAL1, RST)	$2.7 < V_{DD} < 3.3$	$0.7V_{DD}$	$V_{DD} + 0.5$	V
V _{OL}	Output Low Voltage (Ports 1.5, 1.6, 1.7)	V _{DD} = 2.7V			
		$I_{OL} = 16mA$		1.0	V
V _{OL}	Output Low Voltage (Ports 1, 2, 3) ¹	$V_{DD} = 2.7V$			
		$I_{OL} = 100 \mu A^2$		0.3	V
		$I_{OL} = 1.6 \text{mA}^2$		0.45	V
		$I_{OL} = 3.5 \text{mA}^2$		1.0	V
V _{OL1}	Output Low Voltage (Port 0, ALE, PSEN#) ^{1,3}	$V_{DD} = 2.7V$			
		$I_{OL} = 200 \mu A^2$		0.3	V
		$I_{OL} = 3.2 \text{mA}^2$		0.45	V
V _{OH}	Output High Voltage (Ports 1, 2, 3, ALE, PSEN#) ⁴	$V_{DD} = 2.7V$			
		I _{OH} = -10μA	V _{DD} - 0.3		V
		I _{OH} = -30μA	V _{DD} - 0.7		V
		$I_{OH} = -60\mu A$	V _{DD} - 1.5		V
V _{OH1}	Output High Voltage (Port 0 in External Bus Mode) ⁴	$V_{DD} = 2.7V$			
		$I_{OH} = -200 \mu A$	V _{DD} - 0.3		V
		$I_{OH} = -3.2 \text{mA}$	V _{DD} - 0.7		V
V_{BOD}	Brown-out Detection Voltage		2.25	2.55	V
I _{IL}	Logical 0 Input Current (Ports 1, 2, 3)	$V_{IN} = 0.4V$	-1	-75	μΑ
I_{TL}	Logical 1-to-0 Transition Current (Ports 1, 2, 3) ⁵	$V_{IN} = 2V$		-650	μΑ
ILI	Input Leakage Current (Port 0)	$0.45 < V_{IN} < V_{DD}$ -0.3		±10	μΑ
R _{RST}	RST Pulldown Resistor			225	kΩ
C _{IO}	Pin Capacitance ⁶	@ 1 MHz, 25°C		15	pF
I_{DD}	Power Supply Current ⁷				
	In-Application Mode			70	mA
	Active Mode			22	mA
	Idle Mode			6.5	mA
	Standby (Stop Clock) Mode	$T_{amb} = 0$ °C to +70°C		70	μΑ
		$T_{amb} = -40^{\circ}C \text{ to } +85^{\circ}C$		88	μΑ
	Power Down Mode	Minimum V _{DD} = 2V			
		$T_{amb} = 0$ °C to +70°C		40	μΑ
		$T_{amb} = -40^{\circ}C \text{ to } +85^{\circ}C$		50	μA

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1. Under steady state (non-transient) conditions, IOL must be externally limited as follows:

Maximum I_{OL} per port pin: 15mA Maximum I_{OL} per 8-bit port: 26mA Maximum I_{OL} total for all outputs: 71mA

If I_{OL} exceeds the test condition, V_{OH} may exceed the related specification. Pins are not guaranteed to sink current greater than the listed test conditions.

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^{2.} Capacitive loading on Ports 0 & 2 may cause spurious noise to be superimposed on the V_{OL}s of ALE and Ports 1 & 3. The noise due to external bus capacitance discharging into the Port 0 & 2 pins when the pins make 1-to-0 transitions during bus operations. In the worst cases (capacitive loading > 100pF), the noise pulse on the ALE pin may exceed 0.8V. In such cases, it may be desirable to qualify ALE with a Schmitt Trigger, or use an address latch with a Schmitt Trigger STROBE input.

^{3.} Load capacitance for Port 0, ALE & PSEN#= 100pF, load capacitance for all other outputs = 80pF.



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- 4. Capacitive loading on Ports 0 & 2 may cause the V_{OH} on ALE and PSEN# to momentarily fall below the V_{DD} 0.7 specification when the address bits are stabilizing.
- 5. Pins of Ports 1, 2 & 3 source a transition current when they are being externally driven from 1 to 0. The transition current reaches its maximum value when Vin is approximately 2V.
- 6. Pin capacitance is characterized but not tested. EA# is 25pF (max).
- 7. See Figures 10-1, 10-2, 10-3 and 10-4 for test conditions. Minimum V_{DD} for Power Down is 2.0V.

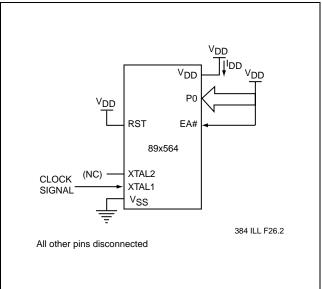


FIGURE 10-1: I_{DD} TEST CONDITION, ACTIVE MODE

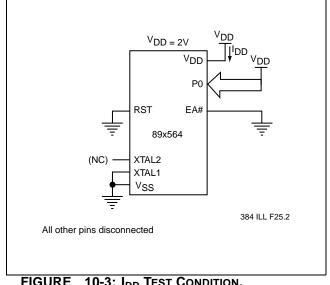


FIGURE 10-3: I_{DD} Test Condition, Power-Down Mode

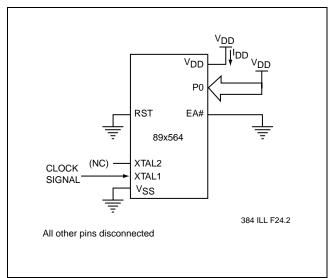


FIGURE 10-2: I_{DD} TEST CONDITION, IDLE MODE

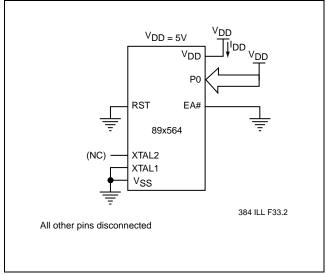


FIGURE 10-4: I_{DD} TEST CONDITION,
STANDBY (STOP CLOCK) MODE



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10.4 AC Electrical Characteristics

AC Characteristics: (Over Operating Conditions: Load Capacitance for Port 0, ALE#, and PSEN# = 100pF; Load Capacitance for All Other Outputs = 80pF)

TABLE 10-5: AC ELECTRICAL CHARACTERISTICS (1 OF 2) $T_{amb} = 0^{\circ}C$ To +70°C OR -40°C TO +85°C, $V_{DD} = 2.7$ -3.6 @25MHz, 4.5-5.5 @ 40MHz, $V_{SS} = 0$

		Oscillator						
Symbol	Parameter	251	ИНz	401	ИНz	Var	iable	Units
		Min	Max	Min	Max	Min	Max	
1/T _{CLCL}	Oscillator Frequency					0	40	MHz
T _{LHLL}	ALE Pulse Width	65		35		2T _{CLCL} - 15		ns
T _{AVLL}	Address Valid to ALE Low	15				T _{CLCL} - 25 (3V)		ns
				10		T _{CLCL} - 15 (5V)		ns
T _{LLAX}	Address Hold After ALE Low	15				T _{CLCL} - 25 (3V)		ns
				10		T _{CLCL} - 15 (5V)		ns
T _{LLIV}	ALE Low to Valid Instr In		95				4T _{CLCL} - 65 (3V)	ns
					55		4T _{CLCL} - 45 (5V)	ns
T _{LLPL}	ALE Low to PSEN# Low	15				T _{CLCL} - 25 (3V)		ns
				10		T _{CLCL} - 15 (5V)		ns
T_{PLPH}	PSEN# Pulse Width	95		60		3T _{CLCL} - 25 (3V) 3T _{CLCL} - 15 (5V)		ns
T _{PLIV}	PSEN# Low to Valid Instr In		65				3T _{CLCL} - 55 (3V)	ns
					25		3T _{CLCL} - 50 (5V)	ns
T_{PXIX}	Input Instr Hold After PSEN#					0		ns
T_{PXIZ}	Input Instr Float After PSEN#		35				T _{CLCL} - 5 (3V)	ns
					10		T _{CLCL} - 15 (5V)	ns
T_{AVIV}	Address to Valid Instr In		120				5T _{CLCL} - 80 (3V)	ns
					65		5T _{CLCL} - 60 (5V)	ns
T _{PLAZ}	PSEN# Low to Address Float		10		10		10	ns
T _{RLRH}	RD# Pulse Width	200		120		6T _{CLCL} - 40 (3V) 6T _{CLCL} - 30 (5V)		ns
T_{WLWH}	Write Pulse Width (WE#)	200		120		6T _{CLCL} - 40 (3V) 6T _{CLCL} - 30 (5V)		ns
T _{RLDV}	RD# Low to Valid Data In		110				5T _{CLCL} - 90 (3V)	ns
					75		5T _{CLCL} - 50 (5V)	ns
T_{RHDX}	Data Hold After RD#	0		0		0		ns
T_{RHDZ}	Data Float After RD#		55				2T _{CLCL} - 25 (3V)	ns
					38		2T _{CLCL} - 12 (5V)	ns
T_{LLDV}	ALE Low to Valid Data In		230				8T _{CLCL} - 90 (3V)	ns
					150		8T _{CLCL} - 50 (5V)	ns
T_{AVDV}	Address to Valid Data In		270				9T _{CLCL} - 90 (3V)	ns
					150		9T _{CLCL} - 75 (5V)	ns
T _{LLWL}	ALE Low to RD# or WR# Low	95	145	60	90	3T _{CLCL} - 25 (3V) 3T _{CLCL} - 15 (5V)	3T _{CLCL} + 25 (3V) 3T _{CLCL} + 15 (5V)	ns
T _{AVWL}	Address to RD# or WR# Low	85				4T _{CLCL} - 75 (3V)		ns
				70		4T _{CLCL} - 30 (5V)		ns
T _{QVWX}	Data Valid to WR# High to Low Transition		0		0		0	ns
T _{WHQX}	Data Hold After WR#	13				T _{CLCL} - 27 (3V)	-	ns
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TABLE 10-5: AC ELECTRICAL CHARACTERISTICS (CONTINUED) (2 of 2)

 $T_{amb} = 0$ °C TO +70°C OR -40°C TO +85°C, $V_{DD} = 2.7$ -3.6 @25MHz, 4.5-5.5 @ 40MHz, $V_{SS} = 0$

		Oscillator						
		25MHz		401	MHz	Variable		7
Symbol	Parameter	Min	Max	Min	Max	Min	Max	Units
T _{QVWH}	Data Valid to WR# High	433				7T _{CLCL} - 70 (3V)		ns
				125		7T _{CLCL} - 50 (5V)		ns
T _{RLAZ}	RD# Low to Address Float		0		0		0	ns
T _{WHLH}	RD# to WR# High to ALE High	43	123			T _{CLCL} - 25 (3V)	T _{CLCL} + 25 (3V)	ns
				10	40	T _{CLCL} - 15 (5V)	T _{CLCL} + 15 (5V)	ns

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10.5 AC Characteristics

Explanation of Symbols Each timing symbol has 5 characters. The first character is always a 'T' (stands for time). The other characters, depending on their positions, stand for the name of a signal or the logical status of that signal. The following is a list of all the characters and what they stand for.

A: Address

C: Clock

D: Input data

H: Logic level HIGH

I: Instruction (program memory contents)

L: Logic level LOW or ALE

P: PSEN#

 V_{IHT}

 V_{ILT}

Q: Output data

R: RD# signal

T: Time

V: Valid

W: WR# signal

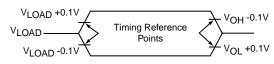
X: No longer a valid logic level

Z: High Impedance (Float)

For example:

T_{AVLL} = Time from Address Valid to ALE Low

T_{LLPL} = Time from ALE Low to PSEN# Low



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AC Inputs during testing are driven at V_{IHT} (V_{DD} -0.5V) for Logic "1" and V_{ILT} (0.45V) for a Logic "0". Measurement reference points for inputs and outputs are at V_{HT} (0.2 V_{DD} + 0.9) and V_{LT} (0.2 V_{DD} - 0.1)

Note: V_{HT}- V_{HIGH} Test V_{LT}- V_{LOW} Test V_{IHT}-V_{INPUT} HIGH Test V_{ILT}- V_{INPUT} LOW Test For timing purposes a port pin is no longer floating when a 100 mV change from load voltage occurs, and begins to float when a 100 mV change from the loaded V_{OH}/V_{OL} level occurs. $I_{OL}/I_{OH} = \pm 20$ mA.

FIGURE 10-5: AC TESTING INPUT/OUTPUT, FLOAT WAVEFORM



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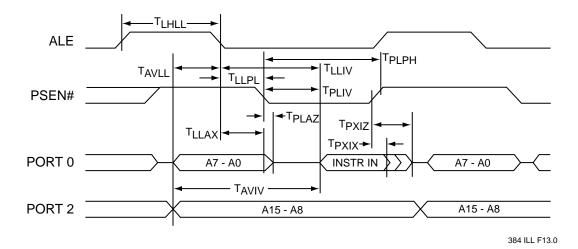


FIGURE 10-6: EXTERNAL PROGRAM MEMORY READ CYCLE

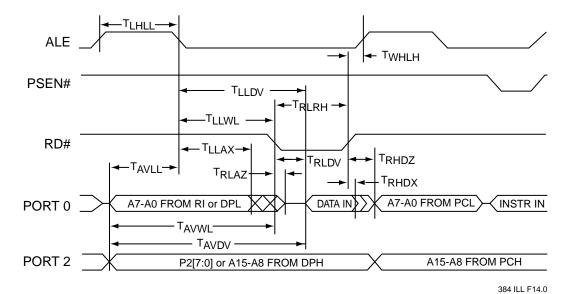


FIGURE 10-7: EXTERNAL DATA MEMORY READ CYCLE

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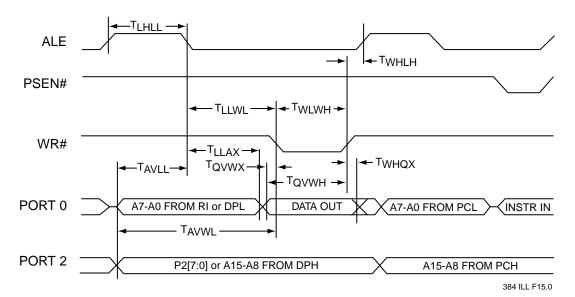


FIGURE 10-8: EXTERNAL DATA MEMORY WRITE CYCLE

TABLE 10-6: EXTERNAL CLOCK DRIVE

		Oscillator						
		25MHz		40MHz		Variable		
Symbol	Parameter	Min	Max	Min	Max	Min	Max	Units
1/T _{CLCL}	Oscillator Frequency					0	40	MHz
T _{CHCX}	High Time					0.35T _{CLCL}	0.65T _{CLCL}	ns
T _{CLCX}	Low Time					0.35T _{CLCL}	0.65T _{CLCL}	ns
T _{CLCH}	Rise Time		20		10			ns
T _{CHCL}	Fall Time		20		10			ns

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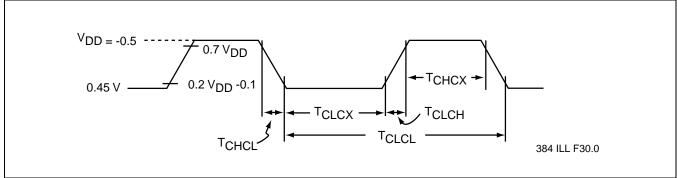


FIGURE 10-9: EXTERNAL CLOCK DRIVE WAVEFORM



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TABLE 10-7: SERIAL PORT TIMING

			Oscillator					
		25MHz		25MHz 40MHz		Variable		
Symbol	Parameter	Min	Max	Min	Max	Min	Max	Units
T _{XLXL}	Serial Port Clock Cycle Time	0		0.36		12T _{CLCL}		ms
T _{QVXH}	Output Data Setup to Clock Rising Edge	700		117		10T _{CLCL} - 133		ns
T _{XHQX}	Output Data Hold After Clock Rising Edge	50				2T _{CLCL} - 117		ns
				0		2T _{CLCL} - 50		ns
T _{XHDX}	Input Data Hold After Clock Rising Edge	0		0		0		ns
T _{XHDV}	Clock Rising Edge to Input Data Valid		700		117		10T _{CLCL} - 133	ns

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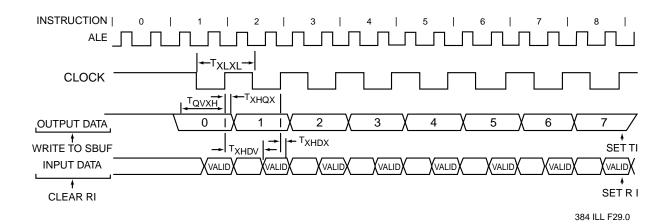
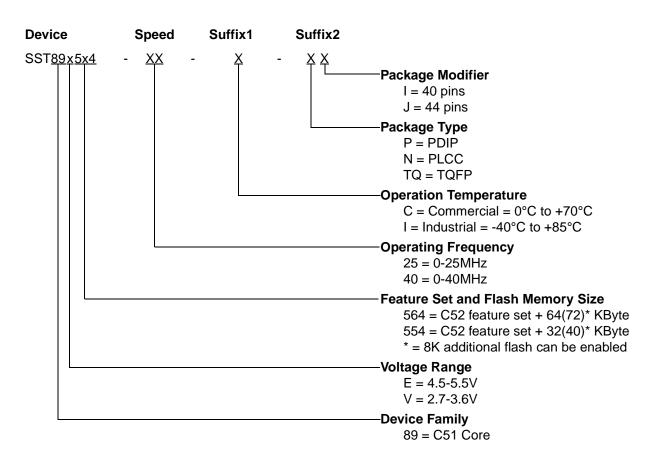


FIGURE 10-10: SHIFT REGISTER MODE TIMING WAVEFORMS



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11.0 PRODUCT ORDERING INFORMATION



11.1 Valid Combinations

Valid combinations for SST89E564

SST89E564-40-C-PI	SST89E564-40-C-NJ	SST89E564-40-C-TQJ
SST89E564-40-I-PI	SST89E564-40-I-NJ	SST89E564-40-I-TQJ

Valid combinations for SST89V564

SST89V564-25-C-PI	SST89V564-25-C-NJ	SST89V564-25-C-TQJ
SST89V564-25-I-PI	SST89V564-25-I-NJ	SST89V564-25-I-TQJ

Valid combinations for SST89E554

SST89E554-40-C-PI	SST89E554-40-C-NJ	SST89E554-40-C-TQJ
SST89E554-40-I-PI	SST89E554-40-I-NJ	SST89E554-40-I-TQJ

Valid combinations for SST89V554

SST89V554-25-C-PI	SST89V554-25-C-NJ	SST89V554-25-C-TQJ
SST89V554-25-I-PI	SST89V554-25-I-NJ	SST89V554-25-I-TQJ

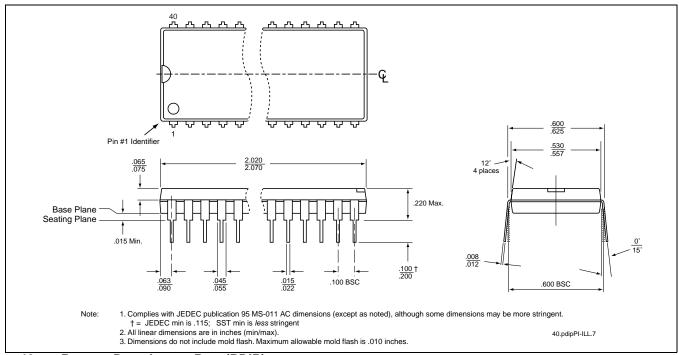
Note: Valid combinations are those products in mass production or will be in mass production.

Consult your SST sales representative to confirm availability of valid combinations and to determine availability of new combinations.



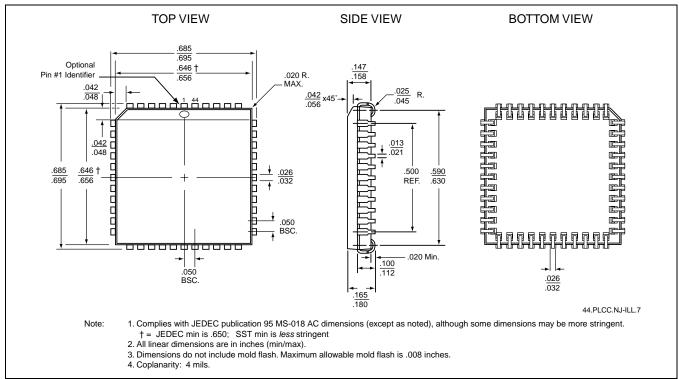
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12.0 PACKAGING DIAGRAMS



40-PIN PLASTIC DUAL IN-LINE PINS (PDIP)

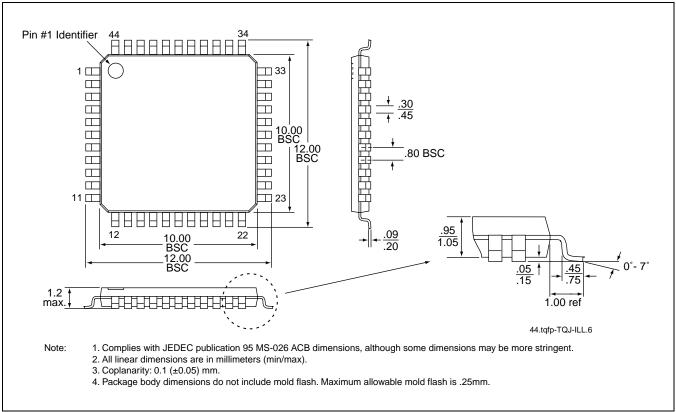
SST PACKAGE CODE: PI



44-LEAD PLASTIC LEAD CHIP CARRIER (PLCC)
SST PACKAGE CODE: NJ



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44-LEAD THIN QUAD FLAT PACK (TQFP)

SST PACKAGE CODE: TQJ

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